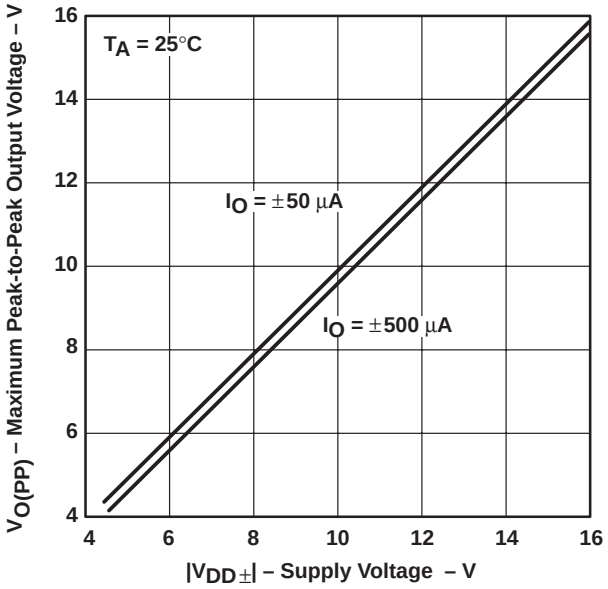
- **Output Swing Includes Both Supply Rails**
- **Low Noise . . . 9 nV/√Hz Typ at f = 1 kHz**
- **Low Input Bias Current . . . 1 pA Typ**
- **Fully Specified for Both Single-Supply and Split-Supply Operation**
- **Common-Mode Input Voltage Range Includes Negative Rail**
- **High-Gain Bandwidth . . . 2.2 MHz Typ**
- **High Slew Rate . . . 3.6 V/μs Typ**
- **Low Input Offset Voltage 950 μV Max at T_A = 25°C**
- **Macromodel Included**
- **Performance Upgrades for the TS272, TS274, TLC272, and TLC274**
- **Available in Q-Temp Automotive HighRel Automotive Applications Configuration Control / Print Support Qualification to Automotive Standards**

description

The TLC2272 and TLC2274 are dual and quadruple operational amplifiers from Texas Instruments. Both devices exhibit rail-to-rail output performance for increased dynamic range in single- or split-supply applications. The TLC227x family offers 2 MHz of bandwidth and 3 V/μs of slew rate for higher speed applications. These devices offer comparable ac performance while having better noise, input offset voltage, and power dissipation than existing CMOS operational amplifiers. The TLC227x has a noise voltage of 9 nV/√Hz, two times lower than competitive solutions.

MAXIMUM PEAK-TO-PEAK OUTPUT VOLTAGE vs SUPPLY VOLTAGE



The TLC227x, exhibiting high input impedance and low noise, is excellent for small-signal conditioning for high-impedance sources, such as piezoelectric transducers. Because of the micro-power dissipation levels, these devices work well in hand-held monitoring and remote-sensing applications. In addition, the rail-to-rail output feature, with single- or split-supplies, makes this family a great choice when interfacing with analog-to-digital converters (ADCs). For precision applications, the TLC227xA family is available and has a maximum input offset voltage of 950 μV. This family is fully characterized at 5 V and ±5 V.

The TLC2272/4 also makes great upgrades to the TLC272/4 or TS272/4 in standard designs. They offer increased output dynamic range, lower noise voltage, and lower input offset voltage. This enhanced feature set allows them to be used in a wider range of applications. For applications that require higher output drive and wider input voltage range, see the TLV2432 and TLV2442 devices.

If the design requires single amplifiers, please see the TLV2211/21/31 family. These devices are single rail-to-rail operational amplifiers in the SOT-23 package. Their small size and low power consumption, make them ideal for high density, battery-powered equipment.

TLC2272 AVAILABLE OPTIONS

T_A	V_{IO}max At 25°C	PACKAGED DEVICES		
		SMALL OUTLINE† (D)	PLASTIC DIP (P)	TSSOP‡ (PW)
0°C to 70°C	950 μV 2.5 mV	TLC2272ACD TLC2272CD	TLC2272ACP TLC2272CP	TLC2272CPW
–40°C to 85°C	950 μV 2.5 mV	TLC2272AID TLC2272ID	TLC2272AIP TLC2272IP	—
–40°C to 125°C	950 μV 2.5 mV	TLC2272AQD TLC2272QD	—	TLC2272AQPW TLC2272QPW
–55°C to 125°C	950 μV 2.5 mV	TLC2272AMD TLC2272MD	TLC2272AMP TLC2272MP	—

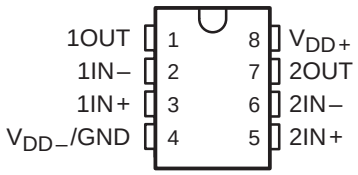
† The D packages are available taped and reeled. Add R suffix to the device type (e.g., TLC2272CDR).
‡ The PW package is available taped and reeled. Add R suffix to the device type (e.g., TLC2272PWR).
§ Chips are tested at 25°C.

TLC2274 AVAILABLE OPTIONS

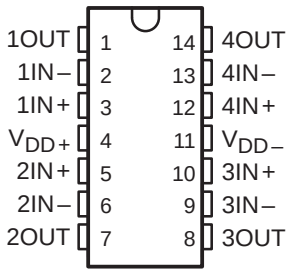
T_A	V_{IO}max AT 25°C	PACKAGED DEVICES				
		SMALL OUTLINE† (D)	CHIP CARRIER (FK)	CERAMIC DIP (J)	PLASTIC DIP (N)	TSSOP‡ (PW)
0°C to 70°C	950 μV 2.5 mV	TLC2274ACD TLC2274CD	—	—	TLC2274ACN TLC2274CN	— TLC2274CPW
–40°C to 85°C	950 μV 2.5 mV	TLC2274AID TLC2274ID	—	—	TLC2274AIN TLC2274IN	— TLC2274IPW
–40°C to 125°C	950 μV 2.5 mV	TLC2274AQD TLC2274QD	—	—	—	—
–55°C to 125°C	950 μV 2.5 mV	TLC2274AMD TLC2274MD	TLC2274AMFK TLC2274MFK	TLC2274AMJ TLC2274MJ	TLC2274AMN TLC2274MN	—

† The D packages are available taped and reeled. Add R suffix to device type (e.g., TLC2274CDR).
‡ The PW package is available taped and reeled.
§ Chips are tested at 25°C.

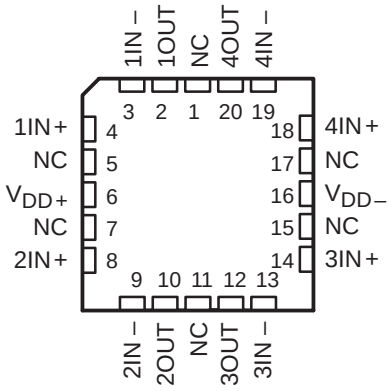
TLC2272
D, P, OR PW PACKAGE
(TOP VIEW)



TLC2274
D, J, N, OR PW PACKAGE
(TOP VIEW)

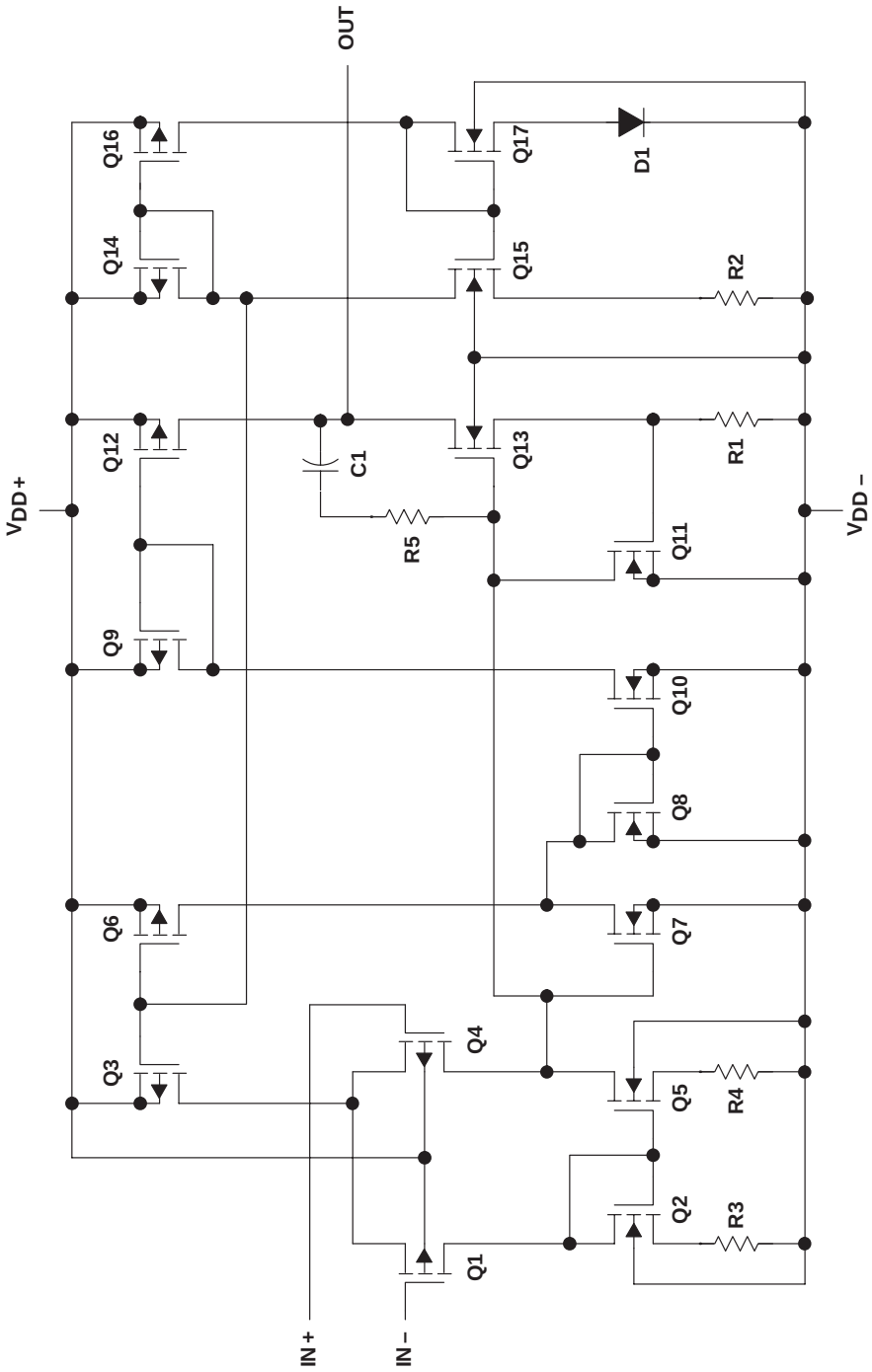


TLC2274
FK PACKAGE
(TOP VIEW)



NC – No internal connection

equivalent schematic (each amplifier)



ACTUAL DEVICE COMPONENT COUNT†		
COMPONENT	TLC2272	TLC2274
Transistors	38	76
Resistors	26	52
Diodes	9	18
Capacitors	3	6

† Includes both amplifiers and all ESD, bias, and trim circuitry

absolute maximum ratings over operating free-air temperature range (unless otherwise noted)†

Supply voltage, V_{DD+} (see Note 1) . . . . . 8 V
Supply voltage, V_{DD-} (see Note 1) . . . . . –8 V
Differential input voltage, V_{ID} (see Note 2) . . . . . ±16 V
Input voltage, V_I (any input, see Note 1) . . . . . V_{DD-} – 0.3 V to V_{DD+}
Input current, I_I (any input) . . . . . ±5 mA
Output current, I_O . . . . . ±50 mA
Total current into V_{DD+} . . . . . ±50 mA
Total current out of V_{DD-} . . . . . ±50 mA
Duration of short-circuit current at (or below) 25°C (see Note 3) . . . . . unlimited
Continuous total dissipation . . . . . See Dissipation Rating Table
Operating free-air temperature range, T_A: C suffix . . . . . 0°C to 70°C
I suffix . . . . . –40°C to 85°C
Q suffix . . . . . –40°C to 125°C
M suffix . . . . . –55°C to 125°C
Storage temperature range . . . . . –65°C to 150°C
Lead temperature 1,6 mm (1/16 inch) from case for 10 seconds: D, N, P or PW package . . . . . 260°C
Lead temperature 1,6 mm (1/16 inch) from case for 60 seconds: J package . . . . . 300°C

† Stresses beyond those listed under “absolute maximum ratings” may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under “recommended operating conditions” is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

NOTES: 1. All voltage values, except differential voltages, are with respect to the midpoint between V_{DD+} and V_{DD-}.
2. Differential voltages are at IN+ with respect to IN–. Excessive current will flow if input is brought below V_{DD-} – 0.3 V.
3. The output may be shorted to either supply. Temperature and/or supply voltages must be limited to ensure that the maximum dissipation rating is not exceeded.

DISSIPATION RATING TABLE

PACKAGE	$T_A \le 25°C$ POWER RATING	DERATING FACTOR ABOVE $T_A = 25°C$	$T_A = 70°C$ POWER RATING	$T_A = 85°C$ POWER RATING	$T_A = 125°C$ POWER RATING
D–8	725 mW	5.8 mW/°C	464 mW	337 mW	145 mW
D–14	950 mW	7.6 mW/°C	608 mW	494 mW	190 mW
FK	1375 mW	11.0 mW/°C	880 mW	715 mW	275 mW
J	1375 mW	11.0 mW/°C	880 mW	715 mW	275 mW
N	1150 mW	9.2 mW/°C	736 mW	598 mW	230 mW
P	1000 mW	8.0 mW/°C	640 mW	520 mW	200 mW
PW–8	525 mW	4.2 mW/°C	336 mW	273 mW	105 mW
PW–14	700 mW	5.6 mW/°C	448 mW	364 mW	—

recommended operating conditions

	C SUFFIX		I SUFFIX		Q SUFFIX		M SUFFIX		UNIT
	MIN	MAX	MIN	MAX	MIN	MAX	MIN	MAX	
Supply voltage, $V_{DD\pm}$	±2.2	±8	±2.2	±8	±2.2	±8	±2.2	±8	V
Input voltage range, V_I	V_{DD-}	V_{DD+} –1.5	V_{DD-}	V_{DD+} –1.5	V_{DD-}	V_{DD+} –1.5	V_{DD-}	V_{DD+} –1.5	V
Common-mode input voltage, V_{IC}	V_{DD-}	V_{DD+} –1.5	V_{DD-}	V_{DD+} –1.5	V_{DD-}	V_{DD+} –1.5	V_{DD-}	V_{DD+} –1.5	V
Operating free-air temperature, T_A	0	70	–40	85	–40	125	–55	125	°C

TLC2272C electrical characteristics at specified free-air temperature, V_{DD} = 5 V (unless otherwise noted)

PARAMETER		TEST CONDITIONS		T_A†	TLC2272C			TLC2272AC			UNIT
					MIN	TYP	MAX	MIN	TYP	MAX	
V_{IO}	Input offset voltage	V_{IC} = 0, V_O = 0,	$V_{DD}\pm$ = ±2.5 V, R_S = 50 Ω	25°C		300	2500		300	950	μV
				Full range			3000			1500	
α_{VIO}	Temperature coefficient of input offset voltage			25°C to 70°C		2			2		μV/°C
	Input offset voltage long-term drift (see Note 4)			25°C		0.002			0.002		μV/mo
I_{IO}	Input offset current			25°C		0.5			0.5		pA
				Full range			100			100	
I_{IB}	Input bias current			25°C		1			1		pA
				Full range			100			100	
V_{ICR}	Common-mode input voltage range	R_S = 50 Ω,	$\lvert V_{IO}\rvert \le$ 5 mV	25°C	0 to 4	−0.3 to 4.2		0 to 4	−0.3 to 4.2		V
				Full range	0 to 3.5			0 to 3.5			
V_{OH}	High-level output voltage	I_{OH} = −20 μA		25°C		4.99			4.99		V
		I_{OH} = −200 μA		25°C	4.85	4.93		4.85	4.93		
				Full range	4.85			4.85			
		I_{OH} = −1 mA		25°C	4.25	4.65		4.25	4.65		
				Full range	4.25			4.25			
V_{OL}	Low-level output voltage	V_{IC} = 2.5 V,	I_{OL} = 50 μA	25°C		0.01			0.01		V
		V_{IC} = 2.5 V,	I_{OL} = 500 μA	25°C		0.09	0.15		0.09	0.15	
				Full range			0.15			0.15	
		V_{IC} = 2.5 V,	I_{OL} = 5 mA	25°C		0.9	1.5		0.9	1.5	
				Full range			1.5			1.5	
A_{VD}	Large-signal differential voltage amplification	V_{IC} = 2.5 V, V_O = 1 V to 4 V	R_L = 10 kΩ‡	25°C	15	35		15	35		V/mV
				Full range	15			15			
			R_L = 1 mΩ‡	25°C		175			175		
r_{id}	Differential input resistance			25°C		10^{12}			10^{12}		Ω
r_i	Common-mode input resistance			25°C		10^{12}			10^{12}		Ω
c_i	Common-mode input capacitance	f = 10 kHz,	P package	25°C		8			8		pF
z_o	Closed-loop output impedance	f = 1 MHz,	A_V = 10	25°C		140			140		Ω
CMRR	Common-mode rejection ratio	V_{IC} = 0 to 2.7 V, V_O = 2.5 V,	R_S = 50 Ω	25°C	70	75		70	75		dB
				Full range	70			70			
k_{SVR}	Supply-voltage rejection ratio ($\Delta V_{DD}/\Delta V_{IO}$)	V_{DD} = 4.4 V to 16 V, V_{IC} = V_{DD}/2,	No load	25°C	80	95		80	95		dB
				Full range	80			80			
I_{DD}	Supply current	V_O = 2.5 V,	No load	25°C		2.2	3		2.2	3	mA
				Full range			3			3	

† Full range is 0°C to 70°C.
‡ Referenced to 2.5 V
NOTE 4: Typical values are based on the input offset voltage shift observed through 168 hours of operating life test at T_A = 150°C extrapolated to T_A = 25°C using the Arrhenius equation and assuming an activation energy of 0.96 eV.

TLC2272C operating characteristics at specified free-air temperature, V_{DD} = 5 V

PARAMETER		TEST CONDITIONS		T_A†	TLC2272C			TLC2272AC			UNIT
					MIN	TYP	MAX	MIN	TYP	MAX	
SR	Slew rate at unity gain	V_O = 0.5 V to 2.5 V, R_L = 10 kΩ‡, C_L = 100 pF‡		25°C	2.3	3.6		2.3	3.6		V/μs
				Full range	1.7			1.7			
V_n	Equivalent input noise voltage	f = 10 Hz		25°C		50			50		nV/√Hz
		f = 1 kHz		25°C		9			9		
V_{NPP}	Peak-to-peak equivalent input noise voltage	f = 0.1 Hz to 1 Hz		25°C		1			1		μV
		f = 0.1 Hz to 10 Hz		25°C		1.4			1.4		
I_n	Equivalent input noise current			25°C		0.6			0.6		fA/√Hz
THD + N	Total harmonic distortion plus noise	V_O = 0.5 V to 2.5 V, f = 20 kHz, R_L = 10 kΩ‡,	A_V = 1	25°C		0.0013%			0.0013%		
			A_V = 10			0.004%			0.004%		
			A_V = 100			0.03%			0.03%		
	Gain-bandwidth product	f = 10 kHz, R_L = 10 kΩ‡, C_L = 100 pF‡		25°C		2.18			2.18		MHz
B_{OM}	Maximum output-swing bandwidth	$V_{O(PP)}$ = 2 V, A_V = 1, R_L = 10 kΩ‡, C_L = 100 pF‡		25°C		1			1		MHz
t_s	Settling time	A_V = −1, Step = 0.5 V to 2.5 V, R_L = 10 kΩ‡, C_L = 100 pF‡	To 0.1%	25°C		1.5			1.5		μs
			To 0.01%			2.6			2.6		
ϕ_m	Phase margin at unity gain	R_L = 10 kΩ‡, C_L = 100 pF‡		25°C		50°			50°		
	Gain margin			25°C		10			10		dB

† Full range is 0°C to 70°C.
‡ Referenced to 2.5 V

TLC2272C electrical characteristics at specified free-air temperature, $V_{DD\pm}$ = ±5 V (unless otherwise specified)

PARAMETER		TEST CONDITIONS		T_A†	TLC2272C			TLC2272AC			UNIT
					MIN	TYP	MAX	MIN	TYP	MAX	
V_{IO}	Input offset voltage	V_{IC} = 0, R_S = 50 Ω	V_O = 0,	25°C		300	2500		300	950	μV
				Full range			3000			1500	
α_{VIO}	Temperature coefficient of input offset voltage			25°C to 70°C		2			2		μV/°C
	Input offset voltage long-term drift (see Note 4)			25°C		0.002			0.002		μV/mo
I_{IO}	Input offset current			25°C		0.5			0.5		pA
				Full range			100			100	
I_{IB}	Input bias current			25°C		1			1		pA
				Full range			100			100	
V_{ICR}	Common-mode input voltage range	R_S = 50 Ω,	$\lvert V_{IO}\rvert \le$5 mV	25°C	−5 to 4	−5.3 to 4.2		−5 to 4	−5.3 to 4.2		V
				Full range	−5 to 3.5			−5 to 3.5			
V_{OM+}	Maximum positive peak output voltage	I_O = −20 μA		25°C		4.99			4.99		V
		I_O = −200 μA		25°C	4.85	4.93		4.85	4.93		
				Full range	4.85			4.85			
		I_O = −1 mA		25°C	4.25	4.65		4.25	4.65		
				Full range	4.25			4.25			
V_{OM-}	Maximum negative peak output voltage	V_{IC} = 0,	I_O = 50 μA	25°C		−4.99			−4.99		V
		V_{IC} = 0,	I_O = 500 μA	25°C	−4.85	−4.91		−4.85	−4.91		
				Full range	−4.85			−4.85			
		V_{IC} = 0,	I_O = 5 mA	25°C	−3.5	−4.1		−3.5	−4.1		
				Full range	−3.5			−3.5			
A_{VD}	Large-signal differential voltage amplification	V_O = ±4 V	R_L = 10 kΩ	25°C	25	50		25	50		V/mV
				Full range	25			25			
			R_L = 1 mΩ	25°C		300			300		
r_{id}	Differential input resistance			25°C		10^{12}			10^{12}		Ω
r_i	Common-mode input resistance			25°C		10^{12}			10^{12}		Ω
c_i	Common-mode input capacitance	f = 10 kHz,	P package	25°C		8			8		pF
z_o	Closed-loop output impedance	f = 1 MHz,	A_V = 10	25°C		130			130		Ω
CMRR	Common-mode rejection ratio	V_{IC} = −5 to 2.7 V, V_O = 0 V,	R_S = 50 Ω	25°C	75	80		75	80		dB
				Full range	75			75			
k_{SVR}	Supply-voltage rejection ratio ($\Delta V_{DD\pm}/\Delta V_{IO}$)	$V_{DD\pm}$ = 2.2 V to ±8 V, V_{IC} = 0,	No load	25°C	80	95		80	95		dB
				Full range	80			80			
I_{DD}	Supply current	V_O = 0 V	No load	25°C		2.4	3		2.4	3	mA
				Full range			3			3	

† Full range is 0°C to 70°C.

NOTE 4: Typical values are based on the input offset voltage shift observed through 168 hours of operating life test at T_A = 150°C extrapolated to T_A = 25°C using the Arrhenius equation and assuming an activation energy of 0.96 eV.

TLC2272C operating characteristics at specified free-air temperature, $V_{DD\pm}$ = ±5 V

PARAMETER		TEST CONDITIONS		T_A†	TLC2272C			TLC2272AC			UNIT
					MIN	TYP	MAX	MIN	TYP	MAX	
SR	Slew rate at unity gain	V_O = ±2.3 V, C_L = 100 pF	R_L = 10 kΩ,	25°C	2.3	3.6		2.3	3.6		V/μs
				Full range	1.7			1.7			
V_n	Equivalent input noise voltage	f = 10 Hz		25°C		50			50		nV/√Hz
		f = 1 kHz		25°C		9			9		
V_{NPP}	Peak-to-peak equivalent input noise voltage	f = 0.1 Hz to 1 Hz		25°C		1			1		μV
		f = 0.1 Hz to 10 Hz		25°C		1.4			1.4		
I_n	Equivalent input noise current			25°C		0.6			0.6		fA/√Hz
THD + N	Total harmonic distortion pulse duration	V_O = ±2.3 V, f = 20 kHz, R_L = 10 kΩ	A_V = 1	25°C		0.0011%			0.0011%		
			A_V = 10			0.004%			0.004%		
			A_V = 100			0.03%			0.03%		
	Gain-bandwidth product	f = 10 kHz, C_L = 100 pF	R_L = 10 kΩ,	25°C		2.25			2.25		MHz
B_{OM}	Maximum output-swing bandwidth	$V_{O(PP)}$ = 4.6 V, R_L = 10 kΩ,	A_V = 1, C_L = 100 pF	25°C		0.54			0.54		MHz
t_s	Settling time	A_V = –1, Step = –2.3 V to 2.3 V, R_L = 10 kΩ, C_L = 100 pF	To 0.1%	25°C		1.5			1.5		μs
			To 0.01%			3.2			3.2		
ϕ_m	Phase margin at unity gain	R_L = 10 kΩ,	C_L = 100 pF	25°C		52°			52°		
	Gain margin			25°C		10			10		dB

† Full range is 0°C to 70°C.

TLC2274C electrical characteristics at specified free-air temperature, V_{DD} = 5 V (unless otherwise noted)

PARAMETER		TEST CONDITIONS		T_A†	TLC2274C			TLC2274AC			UNIT
					MIN	TYP	MAX	MIN	TYP	MAX	
V_{IO}	Input offset voltage	$V_{DD\pm}$ = ±2.5 V, V_O = 0,	V_{IC} = 0, R_S = 50 Ω	25°C		300	2500		300	950	μV
				Full range			3000			1500	
α_{VIO}	Temperature coefficient of input offset voltage			25°C to 70°C		2			2		μV/°C
	Input offset voltage long-term drift (see Note 4)			25°C		0.002			0.002		μV/mo
I_{IO}	Input offset current			25°C		0.5			0.5		pA
				Full range			100			100	
I_{IB}	Input bias current			25°C		1			1		pA
				Full range			100			100	
V_{ICR}	Common-mode input voltage range	R_S = 50Ω,	$\lvert V_{IO}\rvert \le$ 5 m V,	25°C	0 to 4	−0.3 to 4.2		0 to 4	−0.3 to 4.2		V
				Full range	0 to 3.5			0 to 3.5			
V_{OH}	High-level output voltage	I_{OH} = −20 μA		25°C		4.99			4.99		V
		I_{OH} = −200 μA		25°C	4.85	4.93		4.85	4.93		
				Full range	4.85			4.85			
		I_{OH} = −1 mA		25°C	4.25	4.65		4.25	4.65		
				Full range	4.25			4.25			
V_{OL}	Low-level output voltage	V_{IC} = 2.5 V,	I_{OL} = 50 μA	25°C		0.01			0.01		V
		V_{IC} = 2.5 V, I_{OL} = 500 μA		25°C		0.09	0.15		0.09	0.15	
				Full range			0.15			0.15	
		V_{IC} = 2.5 V,	I_{OL} = 5 mA	25°C		0.9	1.5		0.9	1.5	
				Full range			1.5			1.5	
A_{VD}	Large-signal differential voltage amplification	V_{IC} = 2.5 V, V_O = 1 V to 4 V	R_L = 10 kΩ‡	25°C	15	35		15	35		V/mV
				Full range	15			15			
			R_L = 1 mΩ‡	25°C		175			175		
r_{id}	Differential input resistance			25°C		10^{12}			10^{12}		Ω
r_i	Common-mode input resistance			25°C		10^{12}			10^{12}		Ω
c_i	Common-mode input capacitance	f = 10 kHz,	N package	25°C		8			8		pF
z_o	Closed-loop output impedance	f = 1 MHz,	A_V = 10	25°C		140			140		Ω
CMRR	Common-mode rejection ratio	V_{IC} = 0 to 2.7 V, V_O = 2.5 V,	R_S = 50Ω	25°C	70	75		70	75		dB
				Full range	70			70			
k_{SVR}	Supply-voltage rejection ratio ($\Delta V_{DD}/\Delta V_{IO}$)	V_{DD} = 4.4 V to 16 V, V_{IC} = V_{DD}/2,	No load	25°C	80	95		80	95		dB
				Full range	80			80			
I_{DD}	Supply current	V_O = 2.5 V,	No load	25°C		4.4	6		4.4	6	mA
				Full range			6			6	

† Full range is 0°C to 70°C.
‡ Referenced to 2.5 V
NOTE 4: Typical values are based on the input offset voltage shift observed through 168 hours of operating life test at T_A = 150°C extrapolated to T_A = 25°C using the Arrhenius equation and assuming an activation energy of 0.96 eV.

TLC2274C operating characteristics at specified free-air temperature, V_{DD} = 5 V

PARAMETER		TEST CONDITIONS		T_A†	TLC2274C			TLC2274AC			UNIT
					MIN	TYP	MAX	MIN	TYP	MAX	
SR	Slew rate at unity gain	V_O = 0.5 V to 2.5 V, R_L = 10 kΩ‡,	C_L = 100 pF‡	25°C	2.3	3.6		2.3	3.6		V/μs
				Full range	1.7			1.7			
V_n	Equivalent input noise voltage	f = 10 Hz		25°C		50			50		nV/√Hz
		f = 1 kHz		25°C		9			9		
$V_{N(PP)}$	Peak-to-peak equivalent input noise voltage	f = 0.1 to 1 Hz		25°C		1			1		μV
		f = 0.1 to 10 Hz		25°C		1.4			1.4		
I_n	Equivalent input noise current			25°C		0.6			0.6		fA/√Hz
THD + N	Total harmonic distortion plus noise	V_O = 0.5 V to 2.5 V, f = 20 kHz, R_L = 10 kΩ‡	A_V = 1	25°C		0.0013%			0.0013%		
			A_V = 10			0.004%			0.004%		
			A_V = 100			0.03%			0.03%		
	Gain-bandwidth product	f = 10 kHz, C_L = 100 pF‡	R_L = 10 kΩ‡,	25°C		2.18			2.18		MHz
B_{OM}	Maximum output-swing bandwidth	$V_{O(PP)}$ = 2 V, R_L = 10 kΩ‡,	A_V = 1, C_L = 100 pF‡	25°C		1			1		MHz
t_s	Settling time	A_V = –1, Step = 0.5 V to 2.5 V, R_L = 10 kΩ‡, C_L = 100 pF‡	To 0.1%	25°C		1.5			1.5		μs
			To 0.01%			2.6			2.6		
ϕ_m	Phase margin at unity gain	R_L = 10 kΩ‡,	C_L = 100 pF‡	25°C		50°			50°		
	Gain margin			25°C		10			10		dB

† Full range is 0°C to 70°C.
‡ Referenced to 2.5 V

TLC2274C electrical characteristics at specified free-air temperature, $V_{DD\pm}$ = ±5 V (unless otherwise noted)

PARAMETER		TEST CONDITIONS		T_A†	TLC2274C			TLC2274AC			UNIT
					MIN	TYP	MAX	MIN	TYP	MAX	
V_{IO}	Input offset voltage	V_{IC} = 0, V_O = 0, R_S = 50 Ω		25°C		300	2500		300	950	µV
				Full range			3000			1500	
α_{VIO}	Temperature coefficient of input offset voltage			25°C to 70°C		2			2		µV/°C
	Input offset voltage long-term drift (see Note 4)			25°C		0.002			0.002		µV/mo
I_{IO}	Input offset current			25°C		0.5			0.5		pA
				Full range			100			100	
I_{IB}	Input bias current			25°C		1			1		pA
				Full range			100			100	
V_{ICR}	Common-mode input voltage range	R_S = 50 Ω, $\|V_{IO}\| \le$ 5 mV		25°C	−5 to 4	−5.3 to 4.2		−5 to 4	−5.3 to 4.2		V
				Full range	−5 to 3.5			−5 to 3.5			
V_{OM+}	Maximum positive peak output voltage	I_O = −20 µA		25°C		4.99			4.99		V
		I_O = −200 µA		25°C	4.85	4.93		4.85	4.93		
				Full range	4.85			4.85			
		I_O = −1 mA		25°C	4.25	4.65		4.25	4.65		
				Full range	4.25			4.25			
V_{OM-}	Maximum negative peak output voltage	V_{IC} = 0, I_O = 50 µA		25°C		−4.99			−4.99		V
		V_{IC} = 0, I_O = 500 µA		25°C	−4.85	−4.91		−4.85	−4.91		
				Full range	−4.85			−4.85			
		V_{IC} = 0, I_O = −5 mA		25°C	−3.5	−4.1		−3.5	−4.1		
				Full range	−3.5			−3.5			
A_{VD}	Large-signal differential voltage amplification	V_O = ±4 V	R_L = 10 kΩ	25°C	25	50		25	50		V/mV
				Full range	25			25			
			R_L = 1 MΩ	25°C		300			300		
r_{id}	Differential input resistance			25°C		10^{12}			10^{12}		Ω
r_i	Common-mode input resistance			25°C		10^{12}			10^{12}		Ω
c_i	Common-mode input capacitance	f = 10 kHz, N package		25°C		8			8		pF
z_o	Closed-loop output impedance	f = 1 MHz, A_V = 10		25°C		130			130		Ω
CMRR	Common-mode rejection ratio	V_{IC} = −5 V to 2.7 V, V_O = 0, R_S = 50 Ω		25°C	75	80		75	80		dB
				Full range	75			75			
k_{SVR}	Supply-voltage rejection ratio ($\Delta V_{DD\pm}/\Delta V_{IO}$)	$V_{DD\pm}$ = ±2.2 V to ±8 V, V_{IC} = 0, No load		25°C	80	95		80	95		dB
				Full range	80			80			
I_{DD}	Supply current	V_O = 0, No load		25°C		4.8	6		4.8	6	mA
				Full range			6			6	

† Full range is 0°C to 70°C.

NOTE 4: Typical values are based on the input offset voltage shift observed through 168 hours of operating life test at T_A = 150°C extrapolated to T_A = 25°C using the Arrhenius equation and assuming an activation energy of 0.96 eV.

TLC2274C operating characteristics at specified free-air temperature, $V_{DD\pm}$ = ±5 V

PARAMETER		TEST CONDITIONS		T_A†	TLC2274C			TLC2274AC			UNIT
					MIN	TYP	MAX	MIN	TYP	MAX	
SR	Slew rate at unity gain	V_O = ±2.3 V, C_L = 100 pF	R_L = 10 kΩ,	25°C	2.3	3.6		2.3	3.6		V/μs
				Full range	1.7			1.7			
V_n	Equivalent input noise voltage	f = 10 Hz		25°C		50			50		nV/√Hz
		f = 1 Hz		25°C		9			9		
$V_{N(PP)}$	Peak-to-peak equivalent input noise voltage	f = 0.1 Hz to 1 Hz		25°C		1			1		μV
		f = 0.1 Hz to 10 Hz		25°C		1.4			1.4		
I_n	Equivalent input noise current			25°C		0.6			0.6		fA/√Hz
THD + N	Total harmonic distortion plus noise	V_O = ±2.3 V, f = 20 kHz, R_L = 10 kΩ	A_V = 1	25°C		0.0011%			0.0011%		
			A_V = 10			0.004%			0.004%		
			A_V = 100			0.03%			0.03%		
	Gain-bandwidth product	f = 10 kHz, C_L = 100 pF	R_L= 10 kΩ,	25°C		2.25			2.25		MHz
B_{OM}	Maximum output-swing bandwidth	$V_{O(PP)}$ = 4.6 V, R_L = 10 kΩ,	A_V = 1, C_L = 100 pF	25°C		0.54			0.54		MHz
t_s	Settling time	A_V = –1, Step = –2.3 V to 2.3 V, R_L = 10 kΩ, C_L = 100 pF	To 0.1%	25°C		1.5			1.5		μs
			To 0.01%			3.2			3.2		
ϕ_m	Phase margin at unity gain	R_L = 10 kΩ,	C_L = 100 pF	25°C		52°			52°		
	Gain margin			25°C		10			10		dB

† Full range is 0°C to 70°C.

TLC2272I electrical characteristics at specified free-air temperature, V_{DD} = 5 V (unless otherwise noted)

PARAMETER		TEST CONDITIONS		T_A†	TLC2272I			TLC2272AI			UNIT
					MIN	TYP	MAX	MIN	TYP	MAX	
V_{IO}	Input offset voltage	V_{IC} = 0, V_O = 0,	$V_{DD\pm}$ = ±2.5V, R_S = 50 Ω	25°C		300	2500		300	950	μV
				Full range			3000			1500	
α_{VIO}	Temperature coefficient of input offset voltage			25°C to 85°C		2			2		μV/°C
	Input offset voltage long-term drift (see Note 4)			25°C		0.002			0.002		μV/mo
I_{IO}	Input offset current			25°C		0.5			0.5		pA
				Full range			150			150	
I_{IB}	Input bias current			25°C		1			1		pA
				Full range			150			150	
V_{ICR}	Common-mode input voltage range	R_S = 50 Ω,	$\lvert V_{IO}\rvert \le$5 mV	25°C	0 to 4	−0.3 to 4.2		0 to 4	−0.3 to 4.2		V
				Full range	0 to 3.5			0 to 3.5			
V_{OH}	High-level output voltage	I_{OH} = −20 μA		25°C		4.99			4.99		V
		I_{OH} = −200 μA		25°C	4.85	4.93		4.85	4.93		
				Full range	4.85			4.85			
		I_{OH} = −1 mA		25°C	4.25	4.65		4.25	4.65		
				Full range	4.25			4.25			
V_{OL}	Low-level output voltage	V_{IC} = 2.5 V,	I_{OL} = 50 μA	25°C		0.01			0.01		V
		V_{IC} = 2.5 V,	I_{OL} = 500 μA	25°C		0.09	0.15		0.09	0.15	
				Full range			0.15			0.15	
		V_{IC} = 2.5 V,	I_{OL} = 5 mA	25°C		0.9	1.5		0.9	1.5	
				Full range			1.5			1.5	
A_{VD}	Large-signal differential voltage amplification	V_{IC} = 2.5 V, V_O = 1 V to 4 V	R_L = 10 kΩ‡	25°C	15	35		15	35		V/mV
				Full range	15			15			
			R_L = 1 mΩ‡	25°C		175			175		
r_{id}	Differential input resistance			25°C		10^{12}			10^{12}		Ω
r_i	Common-mode input resistance			25°C		10^{12}			10^{12}		Ω
c_i	Common-mode input capacitance	f = 10 kHz,	P package	25°C		8			8		pF
z_o	Closed-loop output impedance	f = 1 MHz,	A_V = 10	25°C		140			140		Ω
CMRR	Common-mode rejection ratio	V_{IC} = 0 to 2.7 V, V_O = 2.5 V,	R_S = 50 Ω	25°C	70	75		70	75		dB
				Full range	70			70			
k_{SVR}	Supply-voltage rejection ratio ($\Delta V_{DD}/\Delta V_{IO}$)	V_{DD} = 4.4 V to 16 V, V_{IC} = V_{DD}/2,	No load	25°C	80	95		80	95		dB
				Full range	80			80			
I_{DD}	Supply current	V_O = 2.5 V,	No load	25°C		2.2	3		2.2	3	mA
				Full range			3			3	

† Full range is – 40°C to 85°C.
‡ Referenced to 2.5 V
NOTE 4: Typical values are based on the input offset voltage shift observed through 168 hours of operating life test at T_A = 150°C extrapolated to T_A = 25°C using the Arrhenius equation and assuming an activation energy of 0.96 eV.

TLC2272I operating characteristics at specified free-air temperature, V_{DD} = 5 V

PARAMETER		TEST CONDITIONS		T_A†	TLC2272I			TLC2272AI			UNIT
					MIN	TYP	MAX	MIN	TYP	MAX	
SR	Slew rate at unity gain	V_O = 0.5 V to 2.5 V, R_L = 10 kΩ‡, C_L = 100 pF‡		25°C	2.3	3.6		2.3	3.6		V/μs
				Full range	1.7			1.7			
V_n	Equivalent input noise voltage	f = 10 Hz		25°C		50			50		nV/√Hz
		f = 1 kHz		25°C		9			9		
V_{NPP}	Peak-to-peak equivalent input noise voltage	f = 0.1 Hz to 1 Hz		25°C		1			1		μV
		f = 0.1 Hz to 10 Hz		25°C		1.4			1.4		
I_n	Equivalent input noise current			25°C		0.6			0.6		fA/√Hz
THD + N	Total harmonic distortion plus noise	V_O = 0.5 V to 2.5 V, f = 20 kHz, R_L = 10 kΩ‡	A_V = 1	25°C		0.0013%			0.0013%		
			A_V = 10			0.004%			0.004%		
			A_V = 100			0.03%			0.03%		
	Gain-bandwidth product	f = 10 kHz, R_L = 10 kΩ‡, C_L = 100 pF‡		25°C		2.18			2.18		MHz
B_{OM}	Maximum output-swing bandwidth	$V_{O(PP)}$ = 2 V, A_V = 1, R_L = 10 kΩ‡, C_L = 100 pF‡		25°C		1			1		MHz
t_s	Settling time	A_V = –1, Step = 0.5 V to 2.5 V, R_L = 10 kΩ‡, C_L = 100 pF‡	To 0.1%	25°C		1.5			1.5		μs
			To 0.01%			2.6			2.6		
ϕ_m	Phase margin at unity gain	R_L = 10 kΩ‡, C_L = 100 pF‡		25°C		50°			50°		
	Gain margin			25°C		10			10		dB

† Full range is – 40°C to 85°C.
‡ Referenced to 2.5 V

TLC2272I electrical characteristics at specified free-air temperature, $V_{DD\pm}$ = ±5 V (unless otherwise noted)

PARAMETER		TEST CONDITIONS		T_A†	TLC2272I			TLC2272AI			UNIT
					MIN	TYP	MAX	MIN	TYP	MAX	
V_{IO}	Input offset voltage	V_{IC} = 0,	V_O = 0,	25°C		300	2500		300	950	μV
		R_S = 50 Ω		Full range			3000			1500	
α_{VIO}	Temperature coefficient of input offset voltage			25°C to 85°C		2			2		μV/°C
	Input offset voltage long-term drift (see Note 4)			25°C		0.002			0.002		μV/mo
I_{IO}	Input offset current			25°C		0.5			0.5		pA
				Full range			150			150	
I_{IB}	Input bias current			25°C		1			1		pA
				Full range			150			150	
V_{ICR}	Common-mode input voltage range	R_S = 50 Ω,	$\lvert V_{IO}\rvert \le$5 mV	25°C	−5 to 4	−5.3 to 4.2		−5 to 4	−5.3 to 4.2		V
				Full range	−5 to 3.5			−5 to 3.5			
V_{OM+}	Maximum positive peak output voltage	I_O = −20 μA		25°C		4.99			4.99		V
		I_O = −200 μA		25°C	4.85	4.93		4.85	4.93		
				Full range	4.85			4.85			
		I_O = −1 mA		25°C	4.25	4.65		4.25	4.65		
				Full range	4.25			4.25			
V_{OM-}	Maximum negative peak output voltage	V_{IC} = 0,	I_O = 50 μA	25°C		−4.99			−4.99		V
		V_{IC} = 0,	I_O = 500 μA	25°C	−4.85	−4.91		−4.85	−4.91		
				Full range	−4.85			−4.85			
		V_{IC} = 0,	I_O = 5 mA	25°C	−3.5	−4.1		−3.5	−4.1		
				Full range	−3.5			−3.5			
A_{VD}	Large-signal differential voltage amplification	V_O = ±4 V	R_L = 10 kΩ	25°C	25	50		25	50		V/mV
				Full range	25			25			
			R_L = 1 mΩ	25°C		300			300		
r_{id}	Differential input resistance			25°C		10^{12}			10^{12}		Ω
r_i	Common-mode input resistance			25°C		10^{12}			10^{12}		Ω
c_i	Common-mode input capacitance	f = 10 kHz,	P package	25°C		8			8		pF
z_o	Closed-loop output impedance	f = 1 MHz,	A_V = 10	25°C		130			130		Ω
CMRR	Common-mode rejection ratio	V_{IC} = 0 to 2.7 V, V_O = 2.5 V,	R_S = 50 Ω	25°C	75	80		75	80		dB
				Full range	75			75			
k_{SVR}	Supply-voltage rejection ratio ($\Delta V_{DD\pm}/\Delta V_{IO}$)	V_{DD} = 4.4 V to 16 V, V_{IC} = V_{DD}/2,	No load	25°C	80	95		80	95		dB
				Full range	80			80			
I_{DD}	Supply current	V_O = 2.5 V,	No load	25°C		2.4	3		2.4	3	mA
				Full range			3			3	

† Full range is – 40°C to 85°C.

NOTE 4: Typical values are based on the input offset voltage shift observed through 168 hours of operating life test at T_A = 150°C extrapolated to T_A = 25°C using the Arrhenius equation and assuming an activation energy of 0.96 eV.

TLC2272I operating characteristics at specified free-air temperature, $V_{DD\pm}$ = ±5 V

PARAMETER		TEST CONDITIONS		T_A†	TLC2272I			TLC2272AI			UNIT
					MIN	TYP	MAX	MIN	TYP	MAX	
SR	Slew rate at unity gain	V_O = ±2.3 V, C_L = 100 pF, R_L = 10 kΩ,		25°C	2.3	3.6		2.3	3.6		V/μs
				Full range	1.7			1.7			
V_n	Equivalent input noise voltage	f = 10 Hz		25°C		50			50		nV/√Hz
		f = 1 kHz		25°C		9			9		
V_{NPP}	Peak-to-peak equivalent input noise voltage	f = 0.1 Hz to 1 Hz		25°C		1			1		μV
		f = 0.1 Hz to 10 Hz		25°C		1.4			1.4		
I_n	Equivalent input noise current			25°C		0.6			0.6		fA/√Hz
THD + N	Total harmonic distortion plus noise	V_O = ±2.3 V, R_L = 10 kΩ, f = 20 kHz	A_V = 1	25°C		0.0011%			0.0011%		
			A_V = 10			0.004%			0.004%		
			A_V = 100			0.03%			0.03%		
	Gain-bandwidth product	f = 10 kHz, C_L = 100 pF, R_L = 10 kΩ,		25°C		2.25			2.25		MHz
B_{OM}	Maximum output-swing bandwidth	$V_{O(PP)}$ = 4.6 V, R_L = 10 kΩ, A_V = 1, C_L = 100 pF		25°C		0.54			0.54		MHz
t_s	Settling time	A_V = –1, Step = –2.3 V to 2.3 V, R_L = 10 kΩ, C_L = 100 pF	To 0.1%	25°C		1.5			1.5		μs
			To 0.01%			3.2			3.2		
ϕ_m	Phase margin at unity gain	R_L = 10 kΩ, C_L = 100 pF		25°C		52°			52°		
	Gain margin			25°C		10			10		dB

† Full range is –40°C to 85°C.

TLC2274I electrical characteristics at specified free-air temperature, V_{DD} = 5 V (unless otherwise noted)

PARAMETER		TEST CONDITIONS		T_A†	TLC2274I			TLC2274AI			UNIT
					MIN	TYP	MAX	MIN	TYP	MAX	
V_{IO}	Input offset voltage	$V_{DD\pm}$ = ±2.5 V, V_O = 0,	V_{IC} = 0, R_S = 50 Ω	25°C		300	2500		300	950	μV
				Full range			3000			1500	
α_{VIO}	Temperature coefficient of input offset voltage			25°C to 85°C		2			2		μV/°C
	Input offset voltage long-term drift (see Note 4)			25°C		0.002			0.002		μV/mo
I_{IO}	Input offset current			25°C		0.5			0.5		pA
				Full range			150			150	
I_{IB}	Input bias current			25°C		1			1		pA
				Full range			150			150	
V_{ICR}	Common-mode input voltage range	R_S = 50 Ω,	$\lvert V_{IO}\rvert \le$ 5 mV	25°C	0 to 4	−0.3 to 4.2		0 to 4	−0.3 to 4.2		V
				Full range	0 to 3.5			0 to 3.5			
V_{OH}	High-level output voltage	I_{OH} = −20 μA		25°C		4.99			4.99		V
		I_{OH} = −200 μA		25°C	4.85	4.93		4.85	4.93		
				Full range	4.85			4.85			
		I_{OH} = −1 mA		25°C	4.25	4.65		4.25	4.65		
				Full range	4.25			4.25			
V_{OL}	Low-level output voltage	V_{IC} = 2.5 V,	I_{OL} = 50 μA	25°C		0.01			0.01		V
		V_{IC} = 2.5 V,	I_{OL} = 500 μA	25°C		0.09	0.15		0.09	0.15	
				Full range			0.15			0.15	
		V_{IC} = 2.5 V,	I_{OL} = 5 mA	25°C		0.9	1.5		0.9	1.5	
				Full range			1.5			1.5	
A_{VD}	Large-signal differential voltage amplification	V_{IC} = 2.5 V, V_O = 1 V to 4 V	R_L = 10 kΩ‡	25°C	15	35		15	35		V/mV
				Full range	15			15			
			R_L = 1 MΩ‡	25°C		175			175		
r_{id}	Differential input resistance			25°C		10^{12}			10^{12}		Ω
r_i	Common-mode input resistance			25°C		10^{12}			10^{12}		Ω
c_i	Common-mode input capacitance	f = 10 kHz,	N package	25°C		8			8		pF
z_o	Closed-loop output impedance	f = 1 MHz,	A_V = 10	25°C		140			140		Ω
CMRR	Common-mode rejection ratio	V_{IC} = 0 to 2.7 V, V_O = 2.5 V,	R_S = 50 Ω	25°C	70	75		70	75		dB
				Full range	70			70			
k_{SVR}	Supply-voltage rejection ratio ($\Delta V_{DD}/\Delta V_{IO}$)	V_{DD} = 4.4 V to 16 V, V_{IC} = V_{DD}/2,	No load	25°C	80	95		80	95		dB
				Full range	80			80			
I_{DD}	Supply current	V_O = 2.5 V,	No load	25°C		4.4	6		4.4	6	mA
				Full range			6			6	

† Full range is – 40°C to 85°C.
‡ Referenced to 2.5 V

NOTE 4: Typical values are based on the input offset voltage shift observed through 168 hours of operating life test at T_A = 150°C extrapolated to T_A = 25°C using the Arrhenius equation and assuming an activation energy of 0.96 eV.

TLC2274I operating characteristics at specified free-air temperature, V_{DD} = 5 V

PARAMETER		TEST CONDITIONS		T_A†	TLC2274I			TLC2274AI			UNIT
					MIN	TYP	MAX	MIN	TYP	MAX	
SR	Slew rate at unity gain	V_O = 0.5 V to 2.5 V, R_L = 10 kΩ‡, C_L = 100 pF‡		25°C	2.3	3.6		2.3	3.6		V/μs
				Full range	1.7			1.7			
V_n	Equivalent input noise voltage	f = 10 Hz		25°C		50			50		nV/√Hz
		f = 1 kHz		25°C		9			9		
$V_{N(PP)}$	Peak-to-peak equivalent input noise voltage	f = 0.1 Hz to 1 Hz		25°C		1			1		μV
		f = 0.1 Hz to 10 Hz		25°C		1.4			1.4		
I_n	Equivalent input noise current			25°C		0.6			0.6		fA/√Hz
THD + N	Total harmonic distortion plus noise	V_O = 0.5 V to 2.5 V, f = 20 kHz, R_L = 10 kΩ‡	A_V = 1	25°C		0.0013%			0.0013%		
			A_V = 10			0.004%			0.004%		
			A_V = 100			0.03%			0.03%		
	Gain-bandwidth product	f = 10 kHz, R_L = 10 kΩ‡, C_L = 100 pF‡		25°C		2.18			2.18		MHz
B_{OM}	Maximum output-swing bandwidth	$V_{O(PP)}$ = 2 V, A_V = 1, R_L = 10 kΩ‡, C_L = 100 pF‡		25°C		1			1		MHz
t_s	Settling time	A_V = –1, Step = 0.5 V to 2.5 V, R_L = 10 kΩ‡, C_L = 100 pF‡	To 0.1%	25°C		1.5			1.5		μs
			To 0.01%			2.6			2.6		
ϕ_m	Phase margin at unity gain	R_L = 10 kΩ‡, C_L = 100 pF‡		25°C		50°			50°		
	Gain margin			25°C		10			10		dB

† Full range is – 40°C to 85°C.
‡ Referenced to 2.5 V

TLC2274I electrical characteristics at specified free-air temperature, $V_{DD\pm}$ = ±5 V (unless otherwise noted)

PARAMETER		TEST CONDITIONS		T_A†	TLC2274I			TLC2274AI			UNIT
					MIN	TYP	MAX	MIN	TYP	MAX	
V_{IO}	Input offset voltage	V_{IC} = 0, V_O = 0, R_S = 50 Ω		25°C		300	2500		300	950	μV
				Full range			3000			1500	
α_{VIO}	Temperature coefficient of input offset voltage			25°C to 85°C		2			2		μV/°C
	Input offset voltage long-term drift (see Note 4)			25°C		0.002			0.002		μV/mo
I_{IO}	Input offset current			25°C		0.5			0.5		pA
				Full range			150			150	
I_{IB}	Input bias current			25°C		1			1		pA
				Full range			150			150	
V_{ICR}	Common-mode input voltage range	R_S = 50 Ω,	|V_{IO}| ≤ 5 mV	25°C	−5 to 4	−5.3 to 4.2		−5 to 4	−5.3 to 4.2		V
				Full range	−5 to 3.5			−5 to 3.5			
V_{OM+}	Maximum positive peak output voltage	I_O = −20 μA		25°C		4.99			4.99		V
		I_O = −200 μA		25°C	4.85	4.93		4.85	4.93		
				Full range	4.85			4.85			
		I_O = −1 mA		25°C	4.25	4.65		4.25	4.65		
				Full range	4.25			4.25			
V_{OM-}	Maximum negative peak output voltage	V_{IC} = 0,	I_O = 50 μA	25°C		−4.99			−4.99		V
		V_{IC} = 0,	I_O = 500 μA	25°C	−4.85	−4.91		−4.85	−4.91		
				Full range	−4.85			−4.85			
		V_{IC} = 0,	I_O = 5 mA	25°C	−3.5	−4.1		−3.5	−4.1		
				Full range	−3.5			−3.5			
A_{VD}	Large-signal differential voltage amplification	V_O = ±4 V	R_L = 10 kΩ	25°C	25	50		25	50		V/mV
				Full range	25			25			
			R_L = 1 MΩ	25°C		300			300		
r_{id}	Differential input resistance			25°C		10^{12}			10^{12}		Ω
r_i	Common-mode input resistance			25°C		10^{12}			10^{12}		Ω
c_i	Common-mode input capacitance	f = 10 kHz,	N package	25°C		8			8		pF
z_o	Closed-loop output impedance	f = 1 MHz,	A_V = 10	25°C		130			130		Ω
CMRR	Common-mode rejection ratio	V_{IC} = −5 to 2.7 V, V_O = 0,	R_S = 50 Ω	25°C	75	80		75	80		dB
				Full range	75			75			
k_{SVR}	Supply-voltage rejection ratio ($\Delta V_{DD\pm}/\Delta V_{IO}$)	$V_{DD\pm}$ = ±2.2 V to ±8 V, V_{IC} = 0,	No load	25°C	80	95		80	95		dB
				Full range	80			80			
I_{DD}	Supply current	V_O = 0,	No load	25°C		4.8	6		4.8	6	mA
				Full range			6			6	

† Full range is – 40°C to 85°C.

NOTE 4: Typical values are based on the input offset voltage shift observed through 168 hours of operating life test at T_A = 150°C extrapolated to T_A = 25°C using the Arrhenius equation and assuming an activation energy of 0.96 eV.

TLC2274I operating characteristics at specified free-air temperature, $V_{DD\pm}$ = ±5 V

PARAMETER		TEST CONDITIONS		T_A†	TLC2274I			TLC2274AI			UNIT
					MIN	TYP	MAX	MIN	TYP	MAX	
SR	Slew rate at unity gain	V_O = ±2.3 V, C_L = 100 pF	R_L = 10 kΩ,	25°C	2.3	3.6		2.3	3.6		V/μs
				Full range	1.7			1.7			
V_n	Equivalent input noise voltage	f = 10 Hz		25°C		50			50		nV/√Hz
		f = 1 kHz		25°C		9			9		
$V_{N(PP)}$	Peak-to-peak equivalent input noise voltage	f = 0.1 Hz to 1 Hz		25°C		1			1		μV
		f = 0.1 Hz to 10 Hz		25°C		1.4			1.4		
I_n	Equivalent input noise current			25°C		0.6			0.6		fA/√Hz
THD + N	Total harmonic distortion plus noise	V_O = ±2.3 V, R_L = 10 kΩ, f = 20 kHz	A_V = 1	25°C		0.0011%			0.0011%		
			A_V = 10			0.004%			0.004%		
			A_V = 100			0.03%			0.03%		
	Gain-bandwidth product	f = 10 kHz, C_L = 100 pF	R_L = 10 kΩ,	25°C		2.25			2.25		MHz
B_{OM}	Maximum output-swing bandwidth	$V_{O(PP)}$ = 4.6 V, R_L = 10 kΩ,	A_V = 1, C_L = 100 pF	25°C		0.54			0.54		MHz
t_s	Settling time	A_V = –1, Step = –2.3 V to 2.3 V, R_L = 10 kΩ, C_L = 100 pF	To 0.1%	25°C		1.5			1.5		μs
			To 0.01%			3.2			3.2		
ϕ_m	Phase margin at unity gain	R_L = 10 kΩ,	C_L = 100 pF	25°C		52°			52°		
	Gain margin			25°C		10			10		dB

† Full range is –40°C to 85°C.

TLC2272Q and TLC2272M electrical characteristics at specified free-air temperature, V_{DD} = 5 V (unless otherwise noted)

PARAMETER		TEST CONDITIONS		T_A†	TLC2272Q, TLC2272M			TLC2272AQ, TLC2272AM			UNIT
					MIN	TYP	MAX	MIN	TYP	MAX	
V_{IO}	Input offset voltage	V_{IC} = 0, V_O = 0,	$V_{DD\pm}$ = ±2.5 V, R_S = 50 Ω	25°C		300	2500		300	950	μV
				Full range			3000			1500	
α_{VIO}	Temperature coefficient of input offset voltage			25°C to 125°C		2			2		μV/°C
	Input offset voltage long-term drift (see Note 4)			25°C		0.002			0.002		μV/mo
I_{IO}	Input offset current			25°C		0.5			0.5		pA
				Full range			500			500	
I_{IB}	Input bias current			25°C		1			1		pA
				Full range			500			500	
V_{ICR}	Common-mode input voltage range	R_S = 50 Ω,	$\lvert V_{IO}\rvert \le$ 5 mV	25°C	0 to 4	−0.3 to 4.2		0 to 4	−0.3 to 4.2		V
				Full range	0 to 3.5			0 to 3.5			
V_{OH}	High-level output voltage	I_{OH} = −20 μA		25°C		4.99			4.99		V
		I_{OH} = −200 μA		25°C	4.85	4.93		4.85	4.93		
				Full range	4.85			4.85			
		I_{OH} = −1 mA		25°C	4.25	4.65		4.25	4.65		
				Full range	4.25			4.25			
V_{OL}	Low-level output voltage	V_{IC} = 2.5 V,	I_{OL} = 50 μA	25°C		0.01			0.01		V
		V_{IC} = 2.5 V,	I_{OL} = 500 μA	25°C		0.09	0.15		0.09	0.15	
				Full range			0.15			0.15	
		V_{IC} = 2.5 V,	I_{OL} = 5 mA	25°C		0.9	1.5		0.9	1.5	
				Full range			1.5			1.5	
A_{VD}	Large-signal differential voltage amplification	V_{IC} = 2.5 V, V_O = 1 V to 4 V	R_L = 10 kΩ‡	25°C	10	35		10	35		V/mV
				Full range	10			10			
			R_L = 1 mΩ‡	25°C		175			175		
r_{id}	Differential input resistance			25°C		10^{12}			10^{12}		Ω
r_i	Common-mode input resistance			25°C		10^{12}			10^{12}		Ω
c_i	Common-mode input capacitance	f = 10 kHz,	P package	25°C		8			8		pF
z_o	Closed-loop output impedance	f = 1 MHz,	A_V = 10	25°C		140			140		Ω
CMRR	Common-mode rejection ratio	V_{IC} = 0 to 2.7 V, V_O = 2.5 V,	R_S = 50 Ω	25°C	70	75		70	75		dB
				Full range	70			70			
k_{SVR}	Supply-voltage rejection ratio ($\Delta V_{DD}/\Delta V_{IO}$)	V_{DD} = 4.4 V to 16 V, V_{IC} = V_{DD}/2,	No load	25°C	80	95		80	95		dB
				Full range	80			80			
I_{DD}	Supply current	V_O = 2.5 V,	No load	25°C		2.2	3		2.2	3	mA
				Full range			3			3	

† Full range is −40°C to 125°C for Q level part, −55°C to 125°C for M level part.
‡ Referenced to 2.5 V
NOTE 4: Typical values are based on the input offset voltage shift observed through 168 hours of operating life test at T_A = 150°C extrapolated to T_A = 25°C using the Arrhenius equation and assuming an activation energy of 0.96 eV.

TLC2272Q and TLC2272M operating characteristics at specified free-air temperature, V_{DD} = 5 V

PARAMETER		TEST CONDITIONS		T_A†	TLC2272Q, TLC2272M			TLC2272AQ, TLC2272AM			UNIT
					MIN	TYP	MAX	MIN	TYP	MAX	
SR	Slew rate at unity gain	V_O = 1.25 V to 2.75 V, R_L = 10 kΩ‡, C_L = 100 pF‡		25°C	2.3	3.6		2.3	3.6		V/μs
				Full range	1.7			1.7			
V_n	Equivalent input noise voltage	f = 10 Hz		25°C		50			50		nV/√Hz
		f = 1 kHz		25°C		9			9		
V_{NPP}	Peak-to-peak equivalent input noise voltage	f = 0.1 Hz to 1 Hz		25°C		1			1		μV
		f = 0.1 Hz to 10 Hz		25°C		1.4			1.4		
I_n	Equivalent input noise current			25°C		0.6			0.6		fA/√Hz
THD + N	Total harmonic distortion plus noise	V_O = 0.5 V to 2.5 V, f = 20 kHz, R_L = 10 kΩ‡,	A_V = 1	25°C		0.0013%			0.0013%		
			A_V = 10			0.004%			0.004%		
			A_V = 100			0.03%			0.03%		
	Gain-bandwidth product	f =10 kHz, R_L = 10 kΩ‡, C_L = 100 pF‡		25°C		2.18			2.18		MHz
B_{OM}	Maximum output-swing bandwidth	$V_{O(PP)}$ = 2 V, A_V = 1, R_L = 10 kΩ‡, C_L = 100 pF‡		25°C		1			1		MHz
t_s	Settling time	A_V = –1, Step = 0.5 V to 2.5 V, R_L = 10 kΩ‡, C_L = 100 pF‡	To 0.1%	25°C		1.5			1.5		μs
			To 0.01%			2.6			2.6		
ϕ_m	Phase margin at unity gain	R_L = 10 kΩ‡, C_L = 100 pF‡		25°C		50°			50°		
	Gain margin			25°C		10			10		dB

† Full range is –40°C to 125°C for Q level part, –55°C to 125°C for M level part.
‡ Referenced to 2.5 V

TLC2272Q and TLC2272M electrical characteristics at specified free-air temperature, $V_{DD\pm}$ = ±5 V (unless otherwise noted)

PARAMETER		TEST CONDITIONS		T_A†	TLC2272Q, TLC2272M			TLC2272AQ, TLC2272AM			UNIT
					MIN	TYP	MAX	MIN	TYP	MAX	
V_{IO}	Input offset voltage	V_{IC} = 0, V_O = 0, R_S = 50 Ω		25°C		300	2500		300	950	μV
				Full range			3000			1500	
α_{VIO}	Temperature coefficient of input offset voltage			25°C to 125°C		2			2		μV/°C
	Input offset voltage long-term drift (see Note 4)			25°C		0.002			0.002		μV/mo
I_{IO}	Input offset current			25°C		0.5			0.5		pA
				Full range			500			500	
I_{IB}	Input bias current			25°C		1			1		pA
				Full range			500			500	
V_{ICR}	Common-mode input voltage range	R_S = 50 Ω,	$\lvert V_{IO}\rvert \le$ 5 mV	25°C	−5 to 4	−5.3 to 4.2		−5 to 4	−5.3 to 4.2		V
				Full range	−5 to 3.5			−5 to 3.5			
V_{OM+}	Maximum positive peak output voltage	I_O = −20 μA		25°C		4.99			4.99		V
		I_O = −200 μA		25°C	4.85	4.93		4.85	4.93		
				Full range	4.85			4.85			
		I_O = −1 mA		25°C	4.25	4.65		4.25	4.65		
				Full range	4.25			4.25			
V_{OM-}	Maximum negative peak output voltage	V_{IC} = 0,	I_O = 50 μA	25°C		−4.99			−4.99		V
		V_{IC} = 0,	I_O = 500 μA	25°C	−4.85	−4.91		−4.85	−4.91		
				Full range	−4.85			−4.85			
		V_{IC} = 0,	I_O = 5 mA	25°C	−3.5	−4.1		−3.5	−4.1		
				Full range	−3.5			−3.5			
A_{VD}	Large-signal differential voltage amplification	V_O = ±4 V	R_L = 10 kΩ	25°C	20	50		20	50		V/mV
				Full range	20			20			
			R_L = 1 mΩ	25°C		300			300		
r_{id}	Differential input resistance			25°C		10^{12}			10^{12}		Ω
r_i	Common-mode input resistance			25°C		10^{12}			10^{12}		Ω
c_i	Common-mode input capacitance	f = 10 kHz,	P package	25°C		8			8		pF
z_o	Closed-loop output impedance	f = 1 MHz,	A_V = 10	25°C		130			130		Ω
CMRR	Common-mode rejection ratio	V_{IC} = −5 to 2.7 V, V_O = 0 V,	R_S = 50 Ω	25°C	75	80		75	80		dB
				Full range	75			75			
k_{SVR}	Supply-voltage rejection ratio ($\Delta V_{DD\pm}/\Delta V_{IO}$)	V_{DD} = ±2.2 V to ±8 V, V_{IC} = 0,	No load	25°C	80	95		80	95		dB
				Full range	80			80			
I_{DD}	Supply current	V_O = 2.5 V,	No load	25°C		2.4	3		2.4	3	mA
				Full range			3			3	

† Full range is −40°C to 125°C for Q level part, −55°C to 125°C for M level part.

NOTE 4: Typical values are based on the input offset voltage shift observed through 168 hours of operating life test at T_A = 150°C extrapolated to T_A = 25°C using the Arrhenius equation and assuming an activation energy of 0.96 eV.

TLC2272Q and TLC2272M operating characteristics at specified free-air temperature, $V_{DD\pm}$ = ±5 V

PARAMETER		TEST CONDITIONS		T_A†	TLC2272Q, TLC2272M			TLC2272AQ, TLC2272AM			UNIT
					MIN	TYP	MAX	MIN	TYP	MAX	
SR	Slew rate at unity gain	V_O = ±1 V, C_L = 100 pF	R_L = 10 kΩ,	25°C	2.3	3.6		2.3	3.6		V/μs
				Full range	1.7			1.7			
V_n	Equivalent input noise voltage	f = 10 Hz		25°C		50			50		nV/√Hz
		f = 1 kHz		25°C		9			9		
V_{NPP}	Peak-to-peak equivalent input noise voltage	f = 0.1 Hz to 1 Hz		25°C		1			1		μV
		f = 0.1 Hz to 10 Hz		25°C		1.4			1.4		
I_n	Equivalent input noise current			25°C		0.6			0.6		fA/√Hz
THD + N	Total harmonic distortion plus noise	V_O = ±2.3 V, R_L = 10 kΩ, f = 20 kHz	A_V = 1	25°C		0.0011%			0.0011%		
			A_V = 10			0.004%			0.004%		
			A_V = 100			0.03%			0.03%		
	Gain-bandwidth product	f =10 kHz, C_L = 100 pF	R_L = 10 kΩ,	25°C		2.25			2.25		MHz
B_{OM}	Maximum output-swing bandwidth	$V_{O(PP)}$ = 4.6 V, R_L = 10 kΩ,	A_V = 1, C_L = 100 pF	25°C		0.54			0.54		MHz
t_s	Settling time	A_V = –1, Step = –2.3 V to 2.3 V, R_L = 10 kΩ, C_L = 100 pF	To 0.1%	25°C		1.5			1.5		μs
			To 0.01%			3.2			3.2		
ϕ_m	Phase margin at unity gain	R_L = 10 kΩ,	C_L = 100 pF	25°C		52°			52°		
	Gain margin			25°C		10			10		dB

† Full range is –40°C to 125°C for Q level part, –55°C to 125°C for M level part.

TLC2274Q and TLC2274M electrical characteristics at specified free-air temperature, V_{DD} = 5 V (unless otherwise noted)

PARAMETER		TEST CONDITIONS		T_A†	TLC2274Q, TLC2274M			TLC2274AQ, TLC2274AM			UNIT
					MIN	TYP	MAX	MIN	TYP	MAX	
V_{IO}	Input offset voltage	$V_{DD\pm}$ = ±2.5 V, V_O = 0,	V_{IC} = 0, R_S = 50 Ω	25°C		300	2500		300	950	μV
				Full range			3000			1500	
α_{VIO}	Temperature coefficient of input offset voltage			25°C to 125°C		2			2		μV/°C
	Input offset voltage long-term drift (see Note 4)			25°C		0.002			0.002		μV/mo
I_{IO}	Input offset current			25°C		0.5			0.5		pA
				Full range			500			500	
I_{IB}	Input bias current			25°C		1			1		pA
				Full range			500			500	
V_{ICR}	Common-mode input voltage range	R_S = 50 Ω,	$\|V_{IO}\| \le$ 5 mV	25°C	0 to 4	−0.3 to 4.2		0 to 4	−0.3 to 4.2		V
				Full range	0 to 3.5			0 to 3.5			
V_{OH}	High-level output voltage	I_{OH} = −20 μA		25°C		4.99			4.99		V
		I_{OH} = −200 μA		25°C	4.85	4.93		4.85	4.93		
				Full range	4.85			4.85			
		I_{OH} = −1 mA		25°C	4.25	4.65		4.25	4.65		
				Full range	4.25			4.25			
V_{OL}	Low-level output voltage	V_{IC} = 2.5 V,	I_{OL} = 50 μA	25°C		0.01			0.01		V
		V_{IC} = 2.5 V, I_{OL} = 500 μA		25°C		0.09	0.15		0.09	0.15	
				Full range			0.15			0.15	
		V_{IC} = 2.5 V,	I_{OL} = 5 mA	25°C		0.9	1.5		0.9	1.5	
				Full range			1.5			1.5	
A_{VD}	Large-signal differential voltage amplification	V_{IC} = 2.5 V, V_O = 1 V to 4 V	R_L = 10 kΩ‡	25°C	10	35		10	35		V/mV
				Full range	10			10			
			R_L = 1 MΩ‡	25°C		175			175		
r_{id}	Differential input resistance			25°C		10^{12}			10^{12}		Ω
r_i	Common-mode input resistance			25°C		10^{12}			10^{12}		Ω
c_i	Common-mode input capacitance	f = 10 kHz,	N package	25°C		8			8		pF
z_o	Closed-loop output impedance	f = 1 MHz,	A_V = 10	25°C		140			140		Ω
CMRR	Common-mode rejection ratio	V_{IC} = 0 to 2.7 V, V_O = 2.5 V,	R_S = 50 Ω	25°C	70	75		70	75		dB
				Full range	70			70			
k_{SVR}	Supply-voltage rejection ratio ($\Delta V_{DD}/\Delta V_{IO}$)	V_{DD} = 4.4 V to 16, V_{IC} = V_{DD}/2,	No load	25°C	80	95		80	95		dB
				Full range	80			80			

† Full range is −40°C to 125°C for Q level part, −55°C to 125°C for M level part.
‡ Referenced to 2.5 V
NOTE 4: Typical values are based on the input offset voltage shift observed through 168 hours of operating life test at T_A = 150°C extrapolated to T_A = 25°C using the Arrhenius equation and assuming an activation energy of 0.96 eV.

TLC2274Q and TLC2274M electrical characteristics at specified free-air temperature, V_{DD} = 5 V (unless otherwise noted) (continued)

PARAMETER		TEST CONDITIONS		T_A†	TLC2274Q, TLC2274M			TLC2274AQ, TLC2274AM			UNIT
					MIN	TYP	MAX	MIN	TYP	MAX	
I_{DD}	Supply current	V_O = 2.5 V,	No load	25°C		4.4	6		4.4	6	mA
				Full range			6			6	

† Full range is –40°C to 125°C for Q level part, –55°C to 125°C for M level part.

TLC2274Q and TLC2274M operating characteristics at specified free-air temperature, V_{DD} = 5 V

PARAMETER		TEST CONDITIONS		T_A†	TLC2274Q, TLC2274M			TLC2274AQ, TLC2274AM			UNIT
					MIN	TYP	MAX	MIN	TYP	MAX	
SR	Slew rate at unity gain	V_O = 0.5 V to 2.5 V, R_L = 10 kΩ‡, C_L = 100 pF‡		25°C	2.3	3.6		2.3	3.6		V/μs
				Full range	1.7			1.7			
V_n	Equivalent input noise voltage	f = 10 Hz		25°C		50			50		nV/√Hz
		f = 1 kHz		25°C		9			9		
$V_{N(PP)}$	Peak-to-peak equivalent input noise voltage	f = 0.1 Hz to 1 Hz		25°C		1			1		μV
		f = 0.1 Hz to 10 Hz		25°C		1.4			1.4		
I_n	Equivalent input noise current			25°C		0.6			0.6		fA/√Hz
THD + N	Total harmonic distortion plus noise	V_O = 0.5 V to 2.5 V, f = 20 kHz, R_L = 10 kΩ‡	A_V = 1	25°C		0.0013%			0.0013%		
			A_V = 10			0.004%			0.004%		
			A_V = 100			0.03%			0.03%		
	Gain-bandwidth product	f = 10 kHz, C_L = 100 pF‡	R_L = 10 kΩ‡,	25°C		2.18			2.18		MHz
B_{OM}	Maximum output-swing bandwidth	$V_{O(PP)}$ = 2 V, R_L = 10 kΩ‡,	A_V = 1, C_L = 100 pF‡	25°C		1			1		MHz
t_s	Settling time	A_V = –1, Step = 0.5 V to 2.5 V, R_L = 10 kΩ‡, C_L = 100 pF‡	To 0.1%	25°C		1.5			1.5		μs
			To 0.01%			2.6			2.6		
ϕ_m	Phase margin at unity gain	R_L = 10 kΩ‡,	C_L = 100 pF‡	25°C		50°			50°		
	Gain margin			25°C		10			10		dB

† Full range is –40°C to 125°C for Q level part, –55°C to 125°C for M level part.
‡ Referenced to 2.5 V

TLC2274Q and TLC2274M electrical characteristics at specified free-air temperature, $V_{DD\pm}$ = ±5 V (unless otherwise noted)

PARAMETER		TEST CONDITIONS		T_A†	TLC2274Q, TLC2274M			TLC2274AQ, TLC2274AM			UNIT
					MIN	TYP	MAX	MIN	TYP	MAX	
V_{IO}	Input offset voltage	V_{IC} = 0, V_O = 0, R_S = 50 Ω		25°C		300	2500		300	950	μV
				Full range			3000			1500	
α_{VIO}	Temperature coefficient of input offset voltage			25°C to 125°C		2			2		μV/°C
	Input offset voltage long-term drift (see Note 4)			25°C		0.002			0.002		μV/mo
I_{IO}	Input offset current			25°C		0.5			0.5		pA
				Full range			500			500	
I_{IB}	Input bias current			25°C		1			1		pA
				Full range			500			500	
V_{ICR}	Common-mode input voltage range	R_S = 50 Ω, $\|V_{IO}\| \le$ 5 mV		25°C	−5 to 4	−5.3 to 4.2		−5 to 4	−5.3 to 4.2		V
				Full range	−5 to 3.5			−5 to 3.5			
V_{OM+}	Maximum positive peak output voltage	I_O = −20 μA		25°C		4.99			4.99		V
		I_O = −200 μA		25°C	4.85	4.93		4.85	4.93		
				Full range	4.85			4.85			
		I_O = −1 mA		25°C	4.25	4.65		4.25	4.65		
				Full range	4.25			4.25			
V_{OM-}	Maximum negative peak output voltage	V_{IC} = 0, I_O = 50 μA		25°C		−4.99			−4.99		V
		V_{IC} = 0, I_O = 500 μA		25°C	−4.85	−4.91		−4.85	−4.91		
				Full range	−4.85			−4.85			
		V_{IC} = 0, I_O = 5 mA		25°C	−3.5	−4.1		−3.5	−4.1		
				Full range	−3.5			−3.5			
A_{VD}	Large-signal differential voltage amplification	V_O = ±4 V	R_L = 10 kΩ	25°C	20	50		20	50		V/mV
				Full range	20			20			
			R_L = 1 MΩ	25°C		300			300		
r_{id}	Differential input resistance			25°C		10^{12}			10^{12}		Ω
r_i	Common-mode input resistance			25°C		10^{12}			10^{12}		Ω
c_i	Common-mode input capacitance	f = 10 kHz, N package		25°C		8			8		pF
z_o	Closed-loop output impedance	f = 1 MHz, A_V = 10		25°C		130			130		Ω
CMRR	Common-mode rejection ratio	V_{IC} = −5 V to 2.7 V, V_O = 0, R_S = 50 Ω		25°C	75	80		75	80		dB
				Full range	75			75			
k_{SVR}	Supply-voltage rejection ratio ($\Delta V_{DD\pm}/\Delta V_{IO}$)	$V_{DD\pm}$ = ± 2.2 V to ±8 V, V_{IC} = 0, No load		25°C	80	95		80	95		dB
				Full range	80			80			

† Full range is −40°C to 125°C for Q level part, −55°C to 125°C for M level part.

NOTE 4: Typical values are based on the input offset voltage shift observed through 168 hours of operating life test at T_A = 150°C extrapolated to T_A = 25°C using the Arrhenius equation and assuming an activation energy of 0.96 eV.

TLC2274Q and TLC2274M electrical characteristics at specified free-air temperature, $V_{DD\pm}$ = ±5 V (unless otherwise noted) (continued)

PARAMETER		TEST CONDITIONS	T_A†	TLC2274Q, TLC2274M			TLC2274AQ, TLC2274AM			UNIT
				MIN	TYP	MAX	MIN	TYP	MAX	
I_{DD}	Supply current	V_O = 0, No load	25°C		4.8	6		4.8	6	mA
			Full range			6			6	

† Full range is –40°C to 125°C for Q level part, –55°C to 125°C for M level part.

TLC2274Q and TLC2274M operating characteristics at specified free-air temperature, $V_{DD\pm}$ = ±5 V

PARAMETER		TEST CONDITIONS		T_A†	TLC2274Q, TLC2274M			TLC2274AQ, TLC2274AM			UNIT
					MIN	TYP	MAX	MIN	TYP	MAX	
SR	Slew rate at unity gain	V_O = ±2.3 V, C_L = 100 pF	R_L = 10 kΩ,	25°C	2.3	3.6		2.3	3.6		V/μs
				Full range	1.7			1.7			
V_n	Equivalent input noise voltage	f = 10 Hz		25°C		50			50		nV/√Hz
		f = 1 kHz		25°C		9			9		
$V_{N(PP)}$	Peak-to-peak equivalent input noise voltage	f = 0.1 Hz to 1 Hz		25°C		1			1		μV
		f = 0.1 Hz to 10 Hz		25°C		1.4			1.4		
I_n	Equivalent input noise current			25°C		0.6			0.6		fA/√Hz
THD + N	Total harmonic distortion plus noise	V_O = ±2.3 V, R_L = 10 kΩ, f = 20 kHz	A_V = 1	25°C		0.0011%			0.0011%		
			A_V = 10			0.004%			0.004%		
			A_V = 100			0.03%			0.03%		
	Gain-bandwidth product	f = 10 kHz, C_L = 100 pF	R_L = 10 kΩ,	25°C		2.25			2.25		MHz
B_{OM}	Maximum output-swing bandwidth	$V_{O(PP)}$ = 4.6 V, R_L = 10 kΩ,	A_V = 1, C_L = 100 pF	25°C		0.54			0.54		MHz
t_s	Settling time	A_V = –1, Step = –2.3 V to 2.3 V, R_L = 10 kΩ, C_L = 100 pF	To 0.1%	25°C		1.5			1.5		μs
			To 0.01%			3.2			3.2		
ϕ_m	Phase margin at unit gain	R_L = 10 kΩ,	C_L = 100 pF	25°C		52°			52°		
	Gain margin			25°C		10			10		dB

† Full range is –40°C to 125°C for Q level part, –55°C to 125°C for M level part.

TYPICAL CHARACTERISTICS

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NOTE: For all graphs where V_{DD} = 5 V, all loads are referenced to 2.5 V.

TYPICAL CHARACTERISTICS

DISTRIBUTION OF TLC2272
INPUT OFFSET VOLTAGE

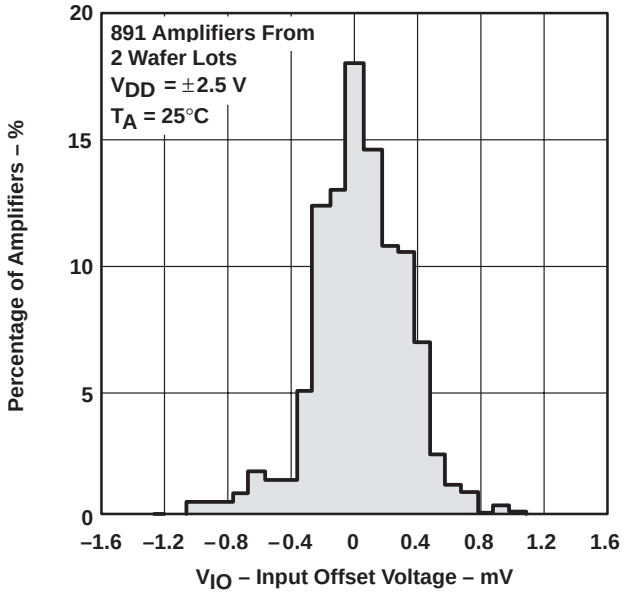


Figure 1

DISTRIBUTION OF TLC2272
INPUT OFFSET VOLTAGE

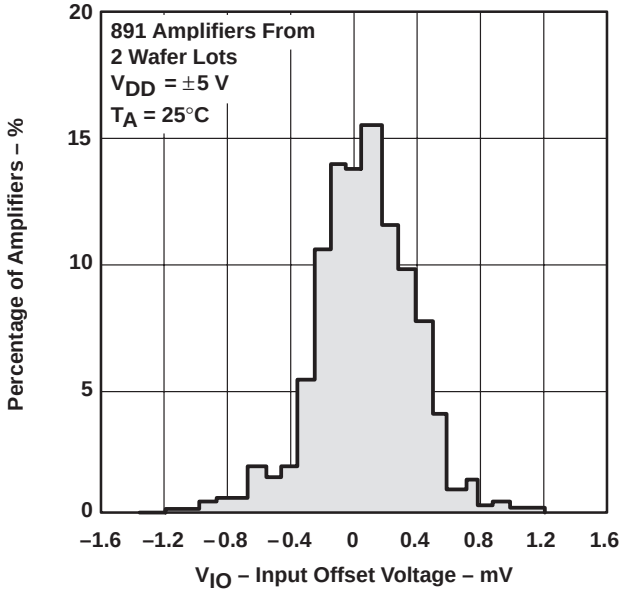


Figure 2

DISTRIBUTION OF TLC2274
INPUT OFFSET VOLTAGE

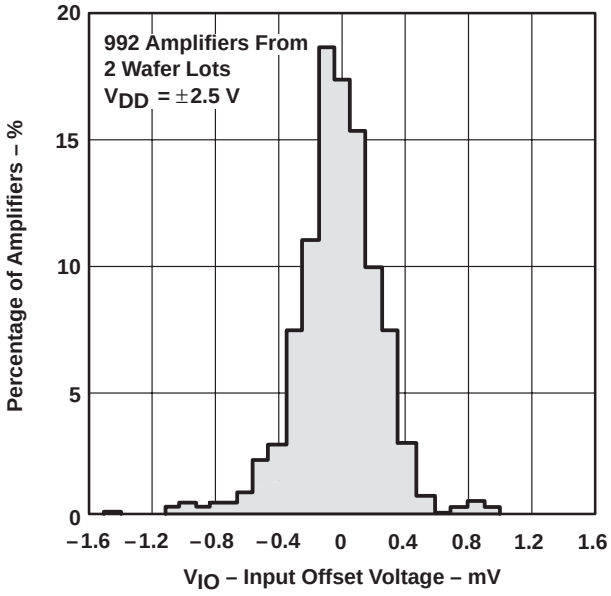


Figure 3

DISTRIBUTION OF TLC2274
INPUT OFFSET VOLTAGE

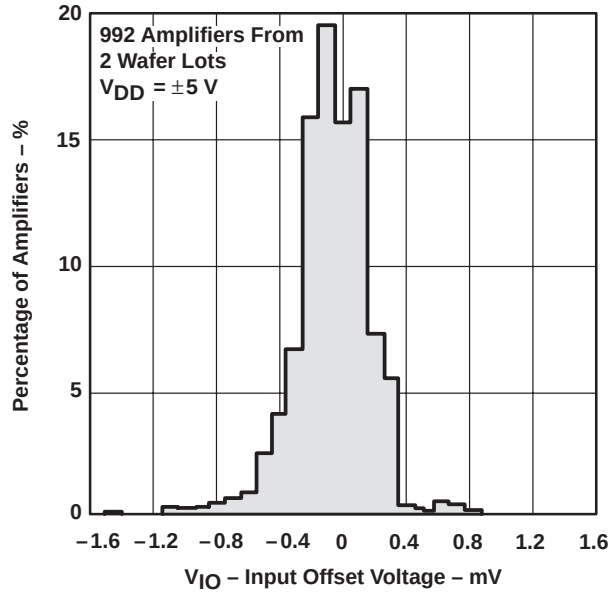


Figure 4

TYPICAL CHARACTERISTICS

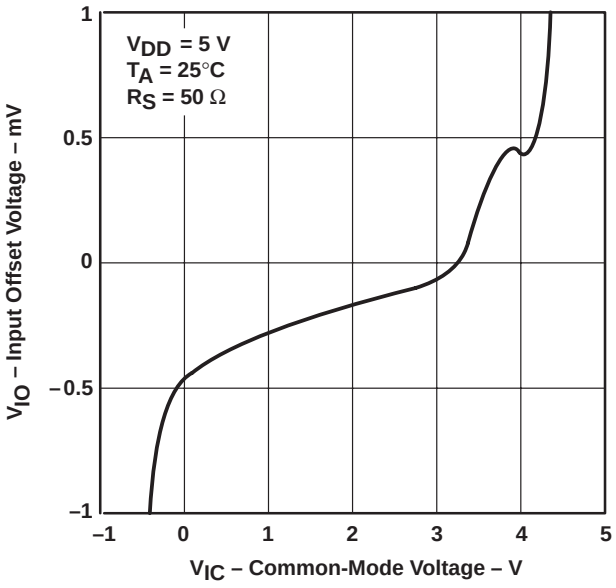


Figure 5

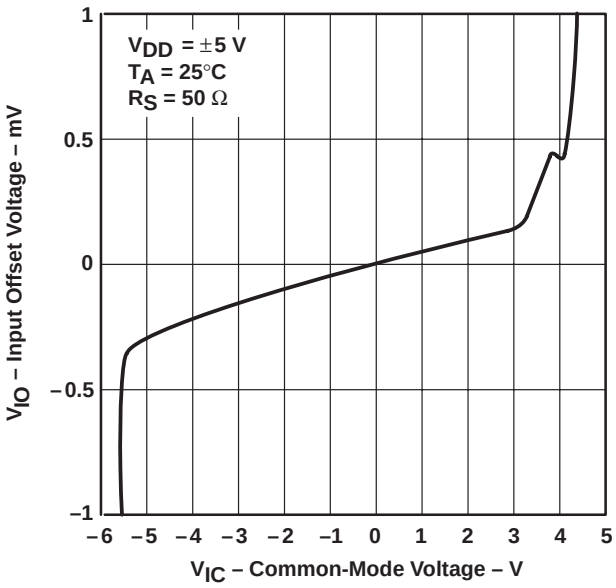


Figure 6

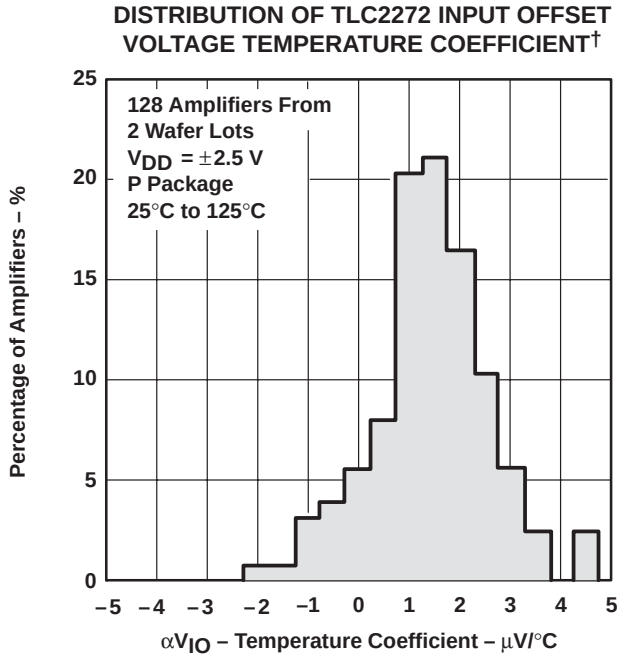


Figure 7

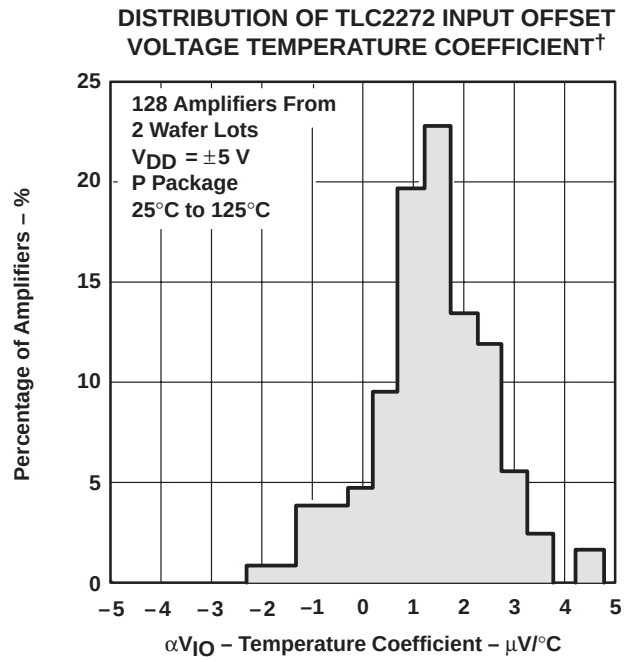


Figure 8

† Data at high and low temperatures are applicable only within the rated operating free-air temperature ranges of the various devices.

TYPICAL CHARACTERISTICS

DISTRIBUTION OF TLC2274 INPUT OFFSET VOLTAGE TEMPERATURE COEFFICIENT†

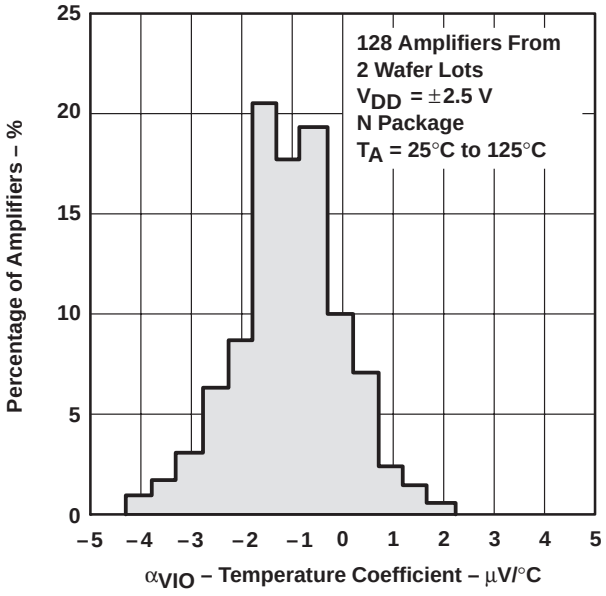


Figure 9

DISTRIBUTION OF TLC2274 INPUT OFFSET VOLTAGE TEMPERATURE COEFFICIENT†

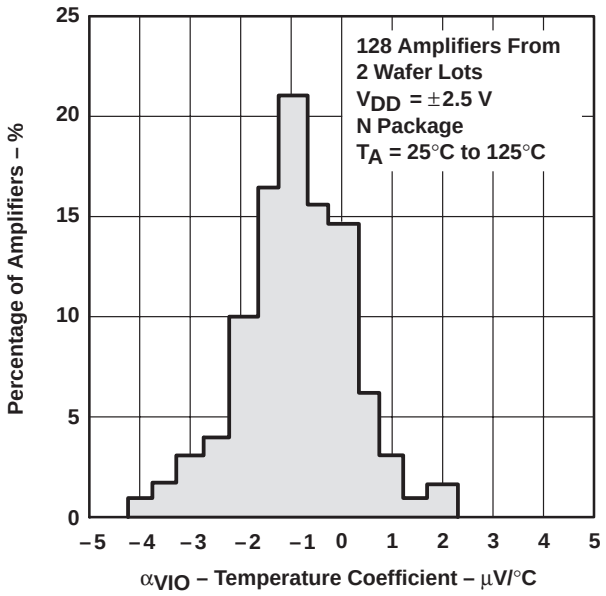


Figure 10

INPUT BIAS AND INPUT OFFSET CURRENT† vs FREE-AIR TEMPERATURE

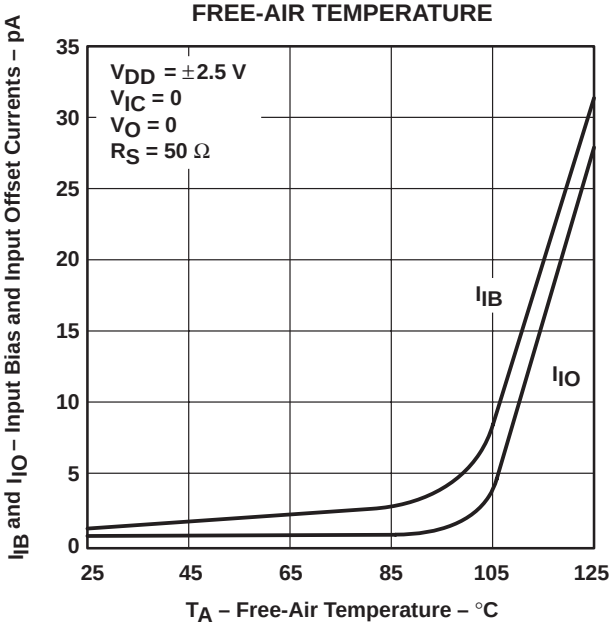


Figure 11

INPUT VOLTAGE RANGE vs SUPPLY VOLTAGE

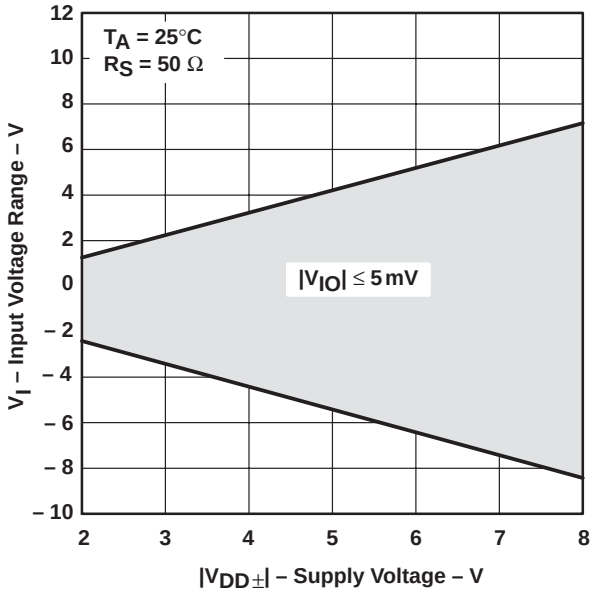


Figure 12

† Data at high and low temperatures are applicable only within the rated operating free-air temperature ranges of the various devices.

TYPICAL CHARACTERISTICS

INPUT VOLTAGE RANGE† vs FREE-AIR TEMPERATURE

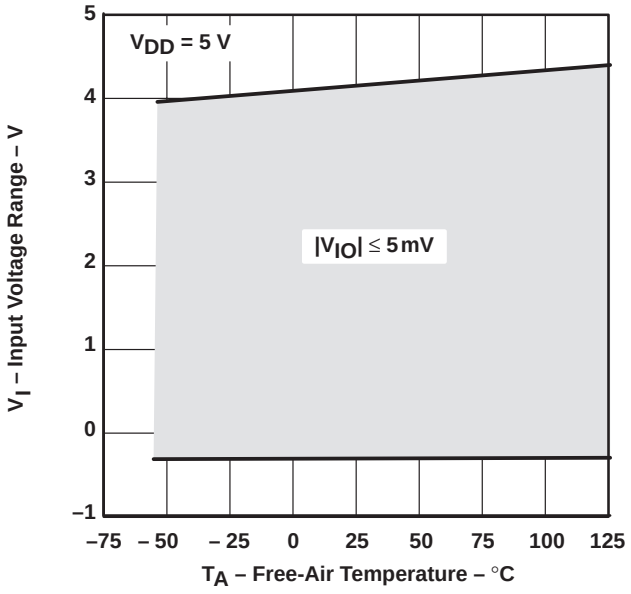


Figure 13

HIGH-LEVEL OUTPUT VOLTAGE† vs HIGH-LEVEL OUTPUT CURRENT

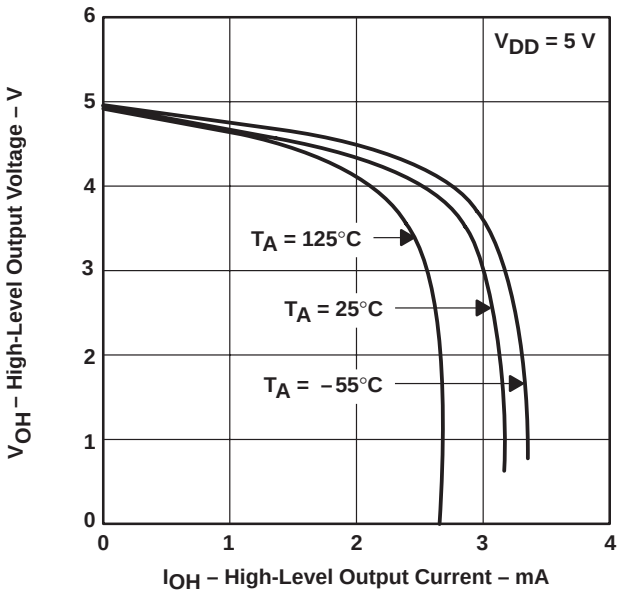


Figure 14

LOW-LEVEL OUTPUT VOLTAGE vs LOW-LEVEL OUTPUT CURRENT

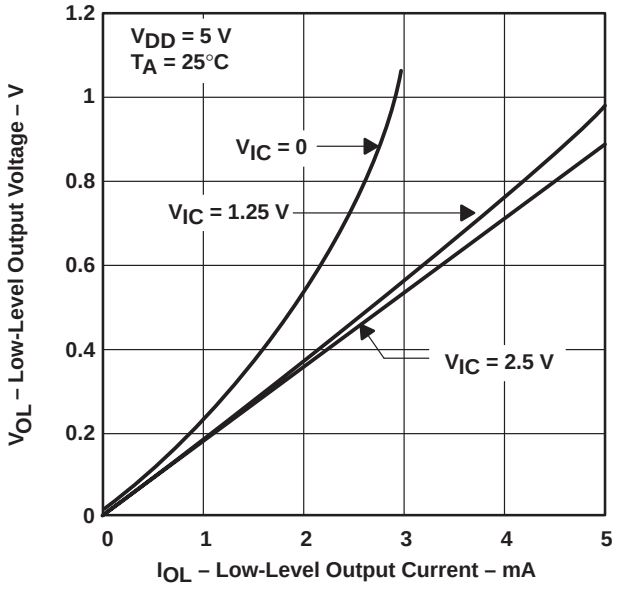


Figure 15

LOW-LEVEL OUTPUT VOLTAGE† vs LOW-LEVEL OUTPUT CURRENT

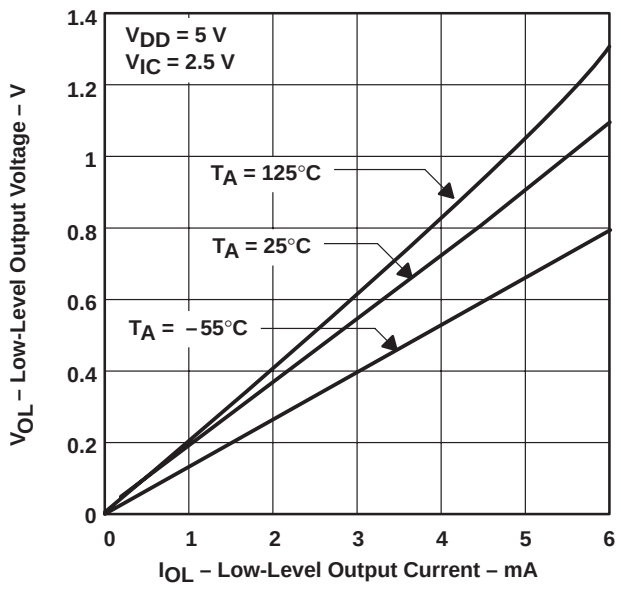


Figure 16

† Data at high and low temperatures are applicable only within the rated operating free-air temperature ranges of the various devices.

TYPICAL CHARACTERISTICS

MAXIMUM POSITIVE PEAK OUTPUT VOLTAGE† vs OUTPUT CURRENT

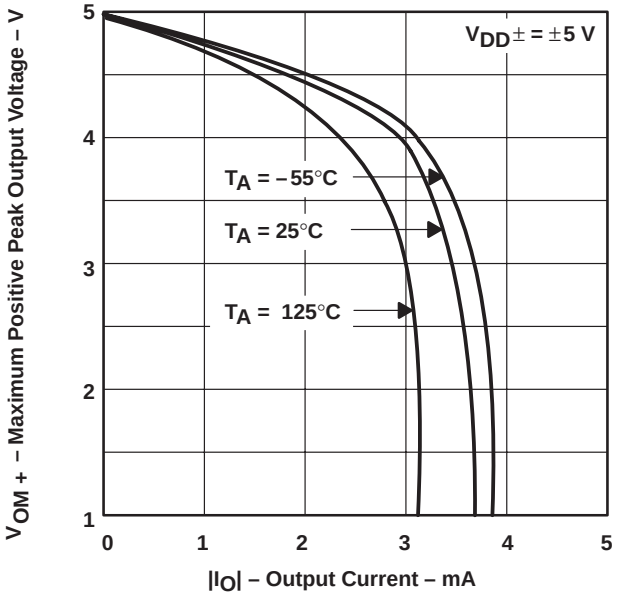


Figure 17

MAXIMUM NEGATIVE PEAK OUTPUT VOLTAGE† vs OUTPUT CURRENT

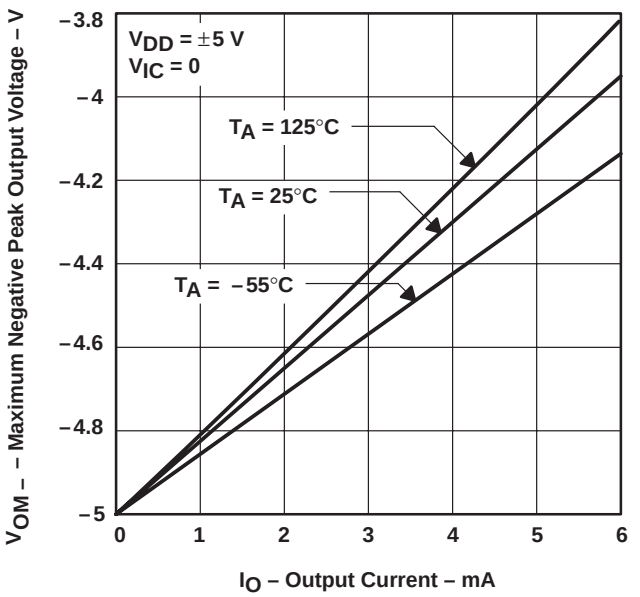


Figure 18

MAXIMUM PEAK-TO-PEAK OUTPUT VOLTAGE vs FREQUENCY

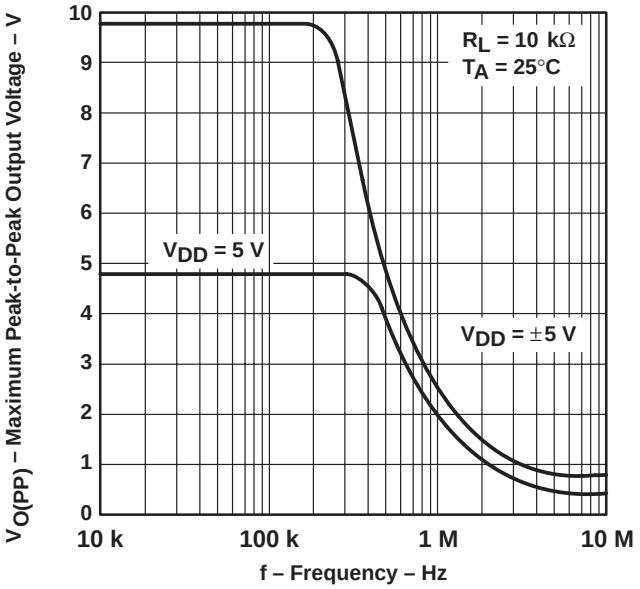


Figure 19

SHORT-CIRCUIT OUTPUT CURRENT vs SUPPLY VOLTAGE

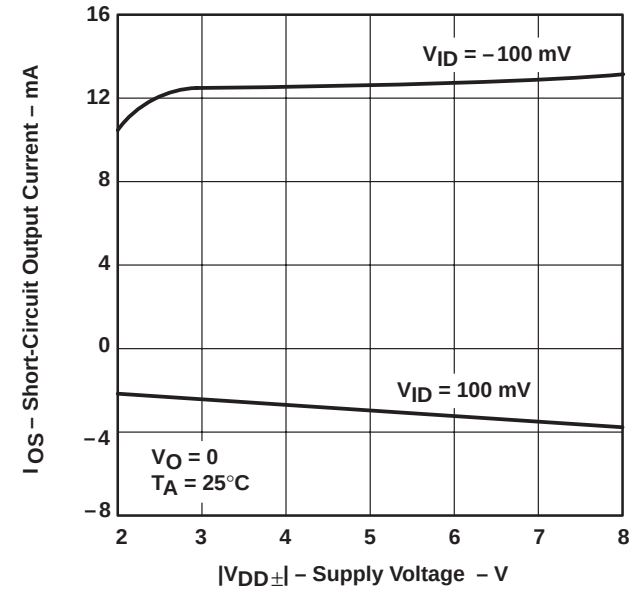


Figure 20

† Data at high and low temperatures are applicable only within the rated operating free-air temperature ranges of the various devices.

TYPICAL CHARACTERISTICS

SHORT-CIRCUIT OUTPUT CURRENT† vs FREE-AIR TEMPERATURE

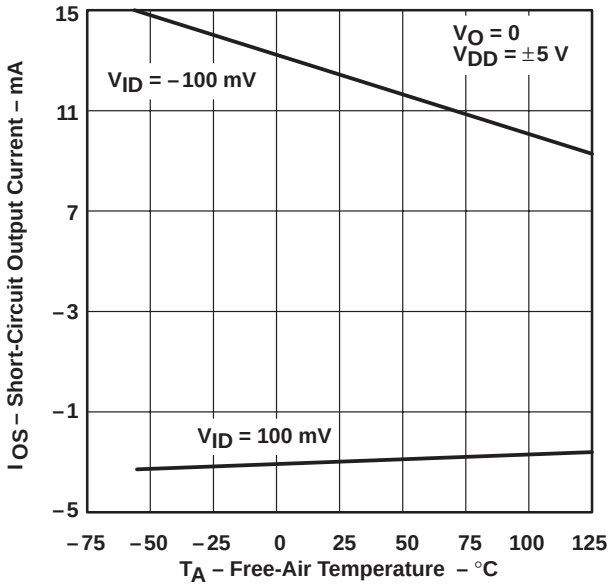


Figure 21

OUTPUT VOLTAGE vs DIFFERENTIAL INPUT VOLTAGE

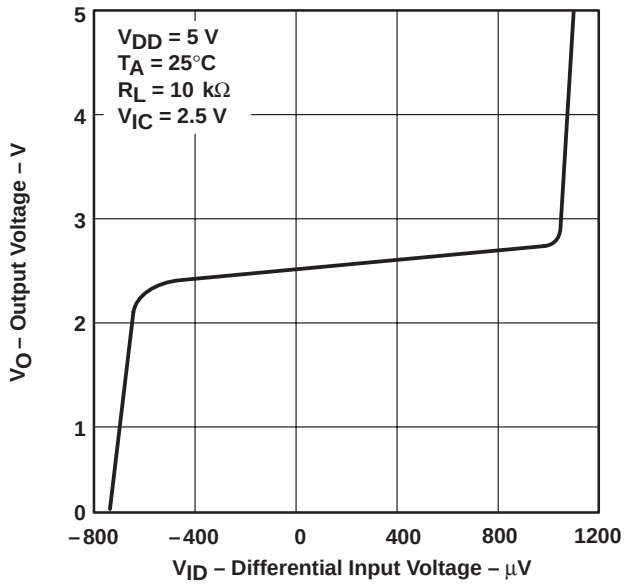


Figure 22

OUTPUT VOLTAGE vs DIFFERENTIAL INPUT VOLTAGE

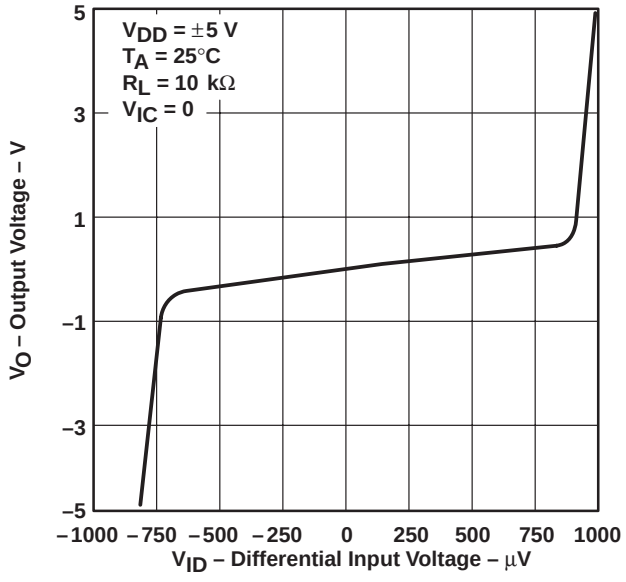


Figure 23

LARGE-SIGNAL DIFFERENTIAL VOLTAGE AMPLIFICATION vs LOAD RESISTANCE

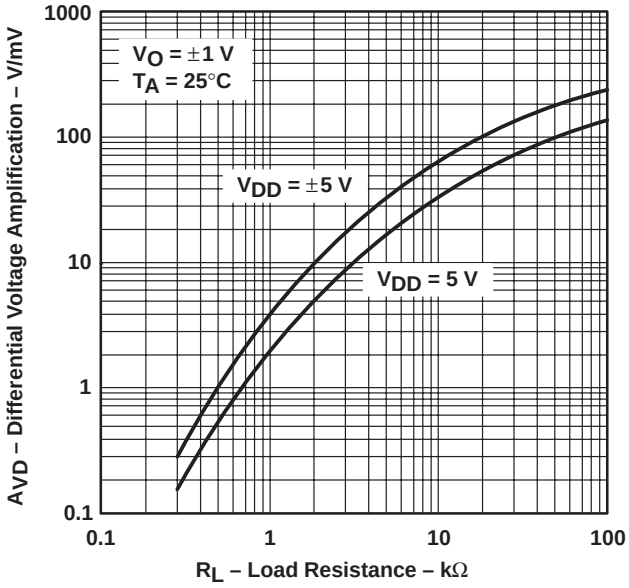


Figure 24

† Data at high and low temperatures are applicable only within the rated operating free-air temperature ranges of the various devices.

TYPICAL CHARACTERISTICS

LARGE-SIGNAL DIFFERENTIAL VOLTAGE AMPLIFICATION AND PHASE MARGIN vs FREQUENCY

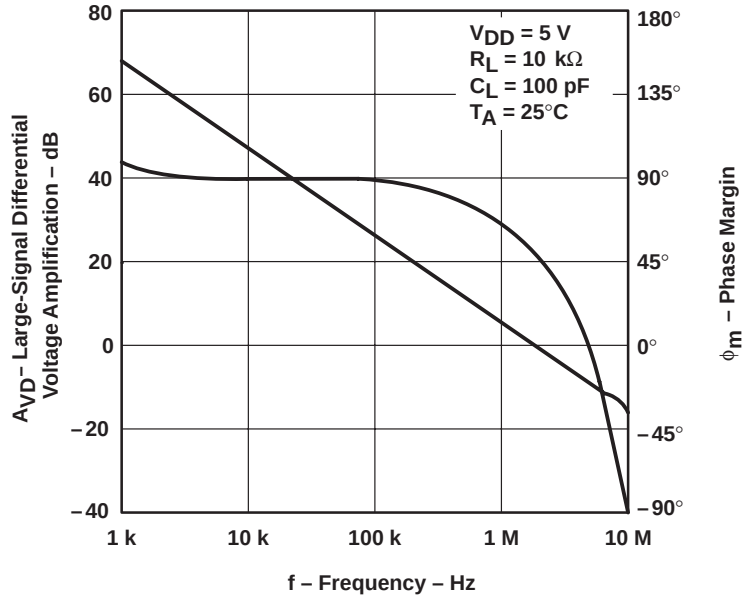


Figure 25

LARGE-SIGNAL DIFFERENTIAL VOLTAGE AMPLIFICATION AND PHASE MARGIN vs FREQUENCY

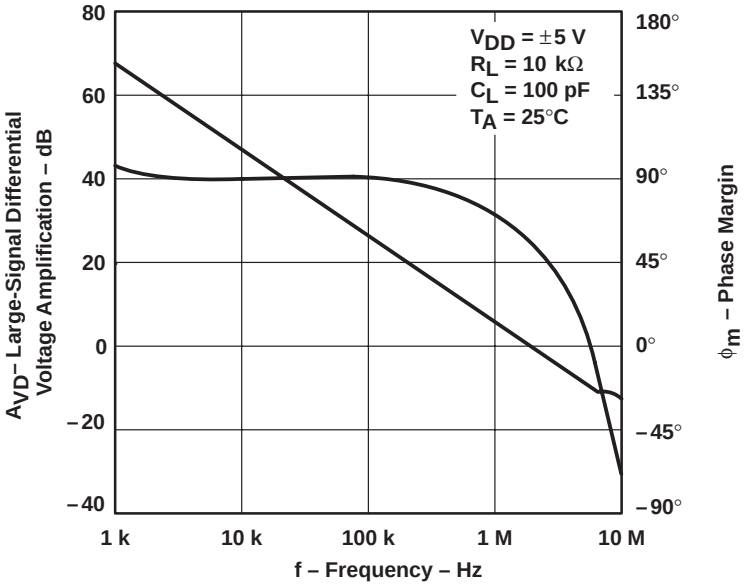


Figure 26

TYPICAL CHARACTERISTICS

LARGE-SIGNAL DIFFERENTIAL VOLTAGE AMPLIFICATION† vs FREE-AIR TEMPERATURE

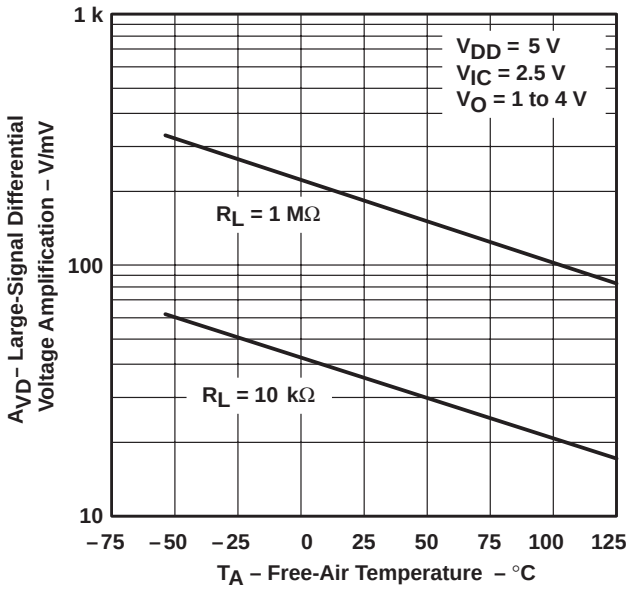


Figure 27

LARGE-SIGNAL DIFFERENTIAL VOLTAGE AMPLIFICATION† vs FREE-AIR TEMPERATURE

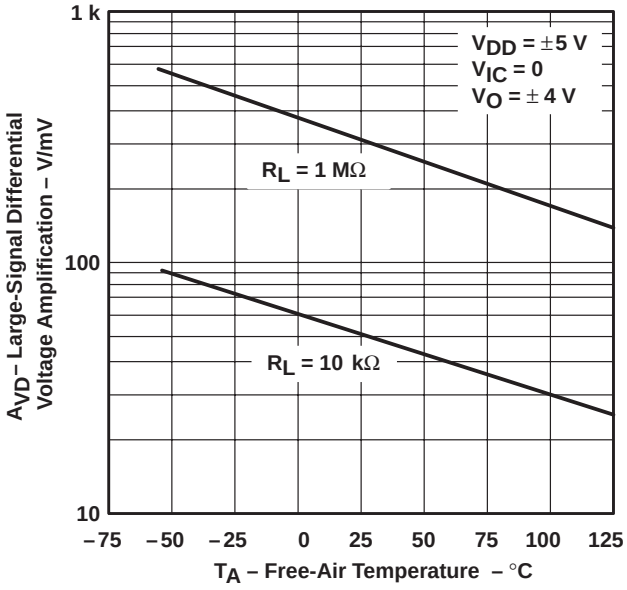


Figure 28

OUTPUT IMPEDANCE vs FREQUENCY

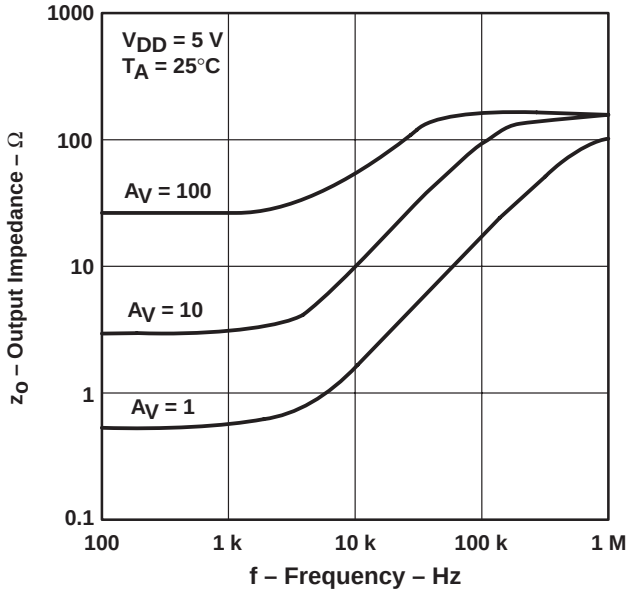


Figure 29

OUTPUT IMPEDANCE vs FREQUENCY

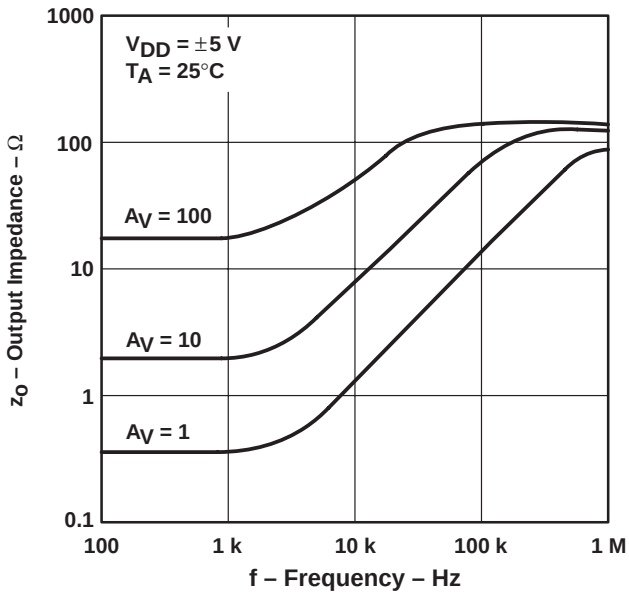


Figure 30

† Data at high and low temperatures are applicable only within the rated operating free-air temperature ranges of the various devices.

TYPICAL CHARACTERISTICS

COMMON-MODE REJECTION RATIO vs FREQUENCY

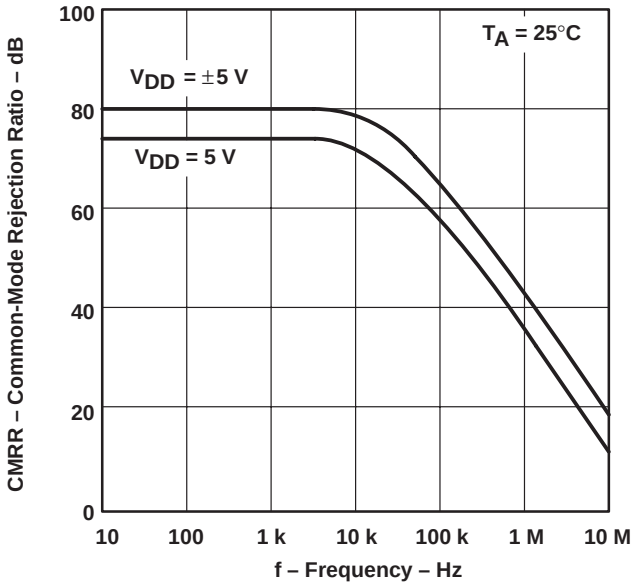


Figure 31

COMMON-MODE REJECTION RATIO vs FREE-AIR TEMPERATURE

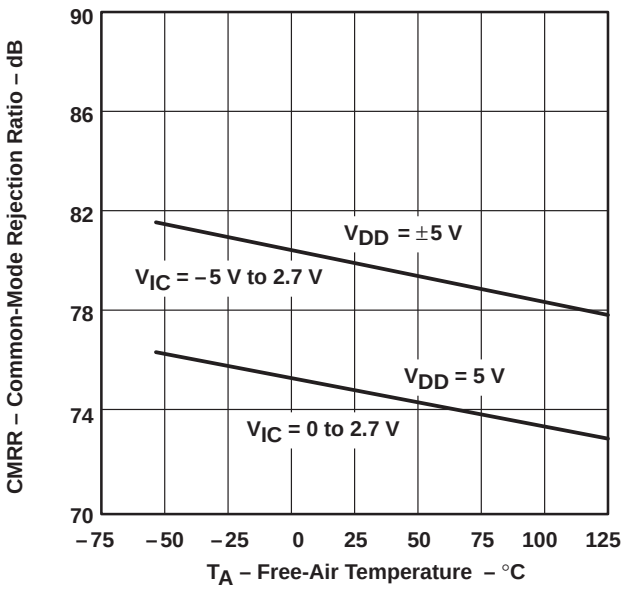


Figure 32

SUPPLY-VOLTAGE REJECTION RATIO vs FREQUENCY

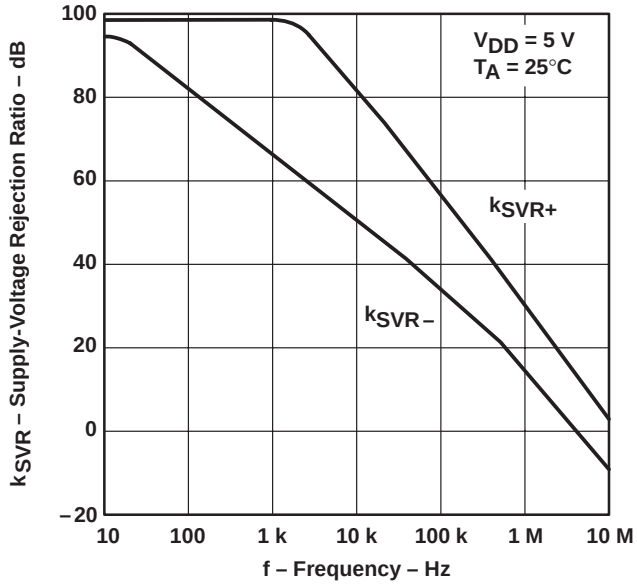


Figure 33

SUPPLY-VOLTAGE REJECTION RATIO vs FREQUENCY

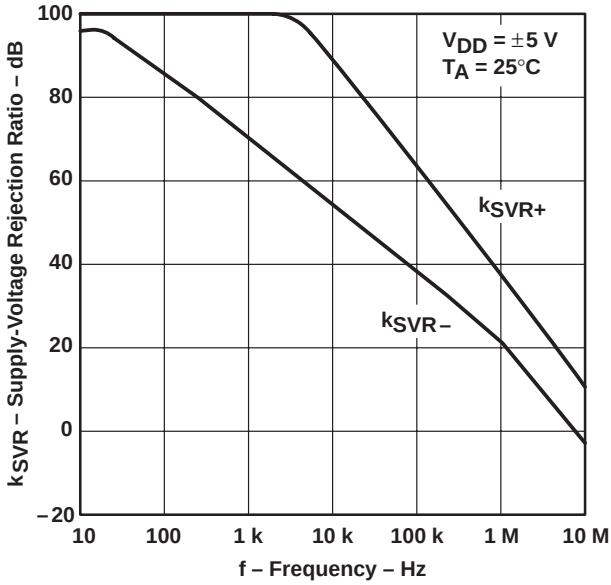


Figure 34

TYPICAL CHARACTERISTICS

SUPPLY VOLTAGE REJECTION RATIO† vs FREE-AIR TEMPERATURE

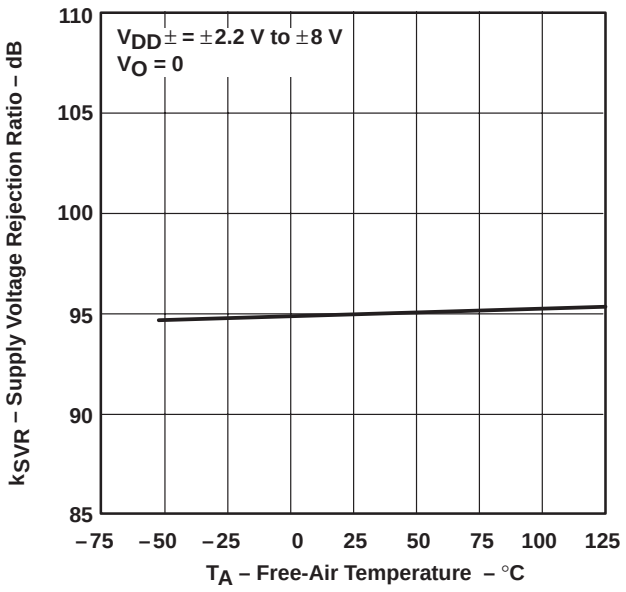


Figure 35

TLC2272 SUPPLY CURRENT† vs SUPPLY VOLTAGE

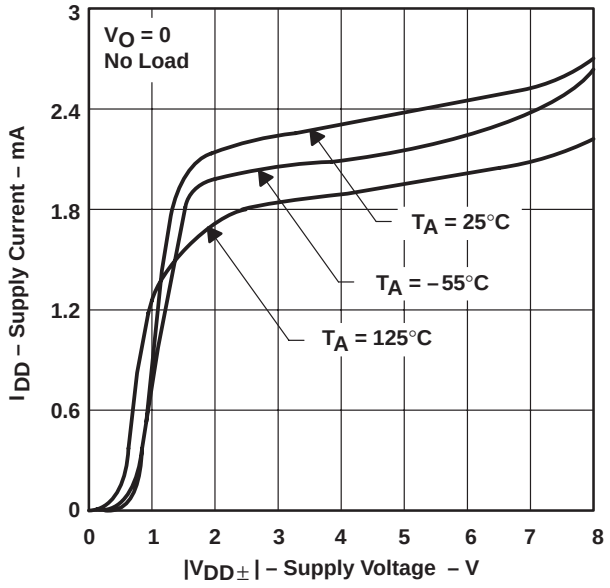


Figure 36

TLC2274 SUPPLY CURRENT† vs SUPPLY VOLTAGE

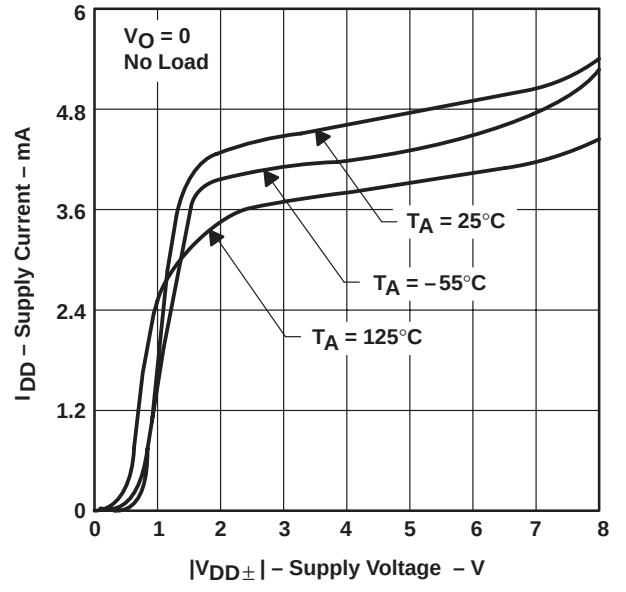


Figure 37

TLC2272 SUPPLY CURRENT† vs FREE-AIR TEMPERATURE

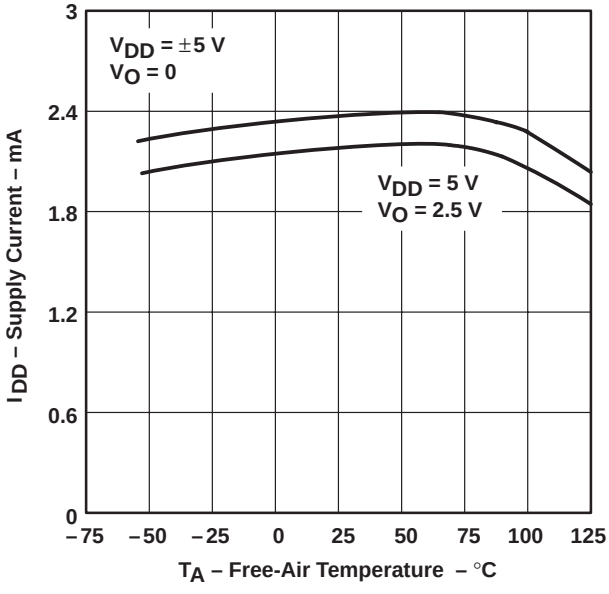


Figure 38

† Data at high and low temperatures are applicable only within the rated operating free-air temperature ranges of the various devices.

TYPICAL CHARACTERISTICS

TLC2274
SUPPLY CURRENT† vs FREE-AIR TEMPERATURE

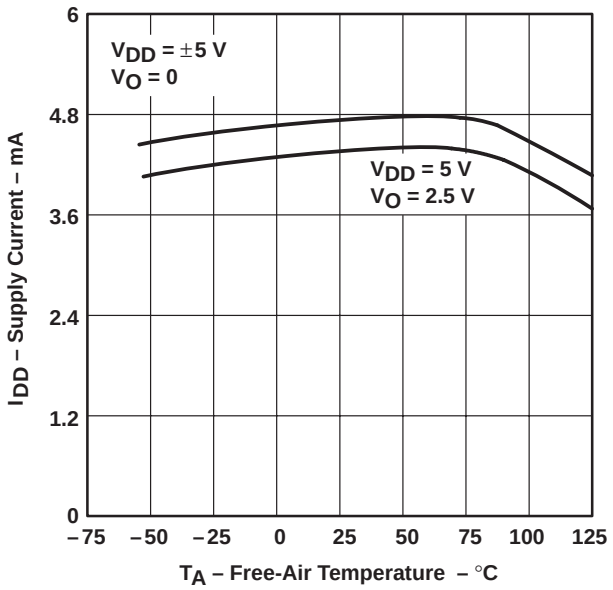


Figure 39

SLEW RATE vs LOAD CAPACITANCE

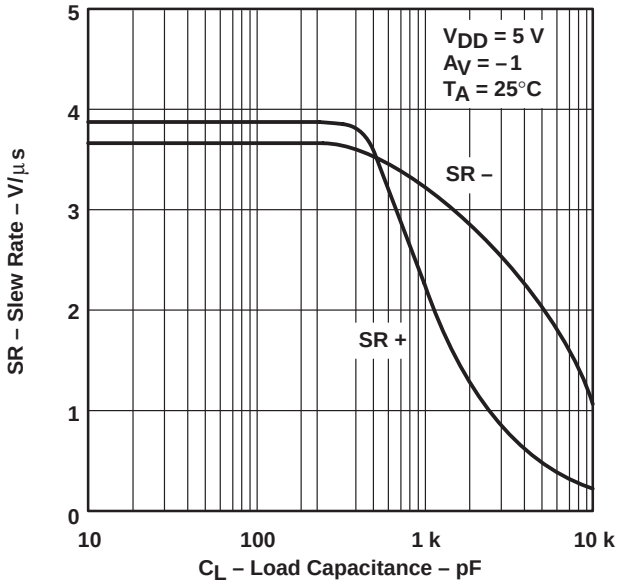


Figure 40

SLEW RATE† vs FREE-AIR TEMPERATURE

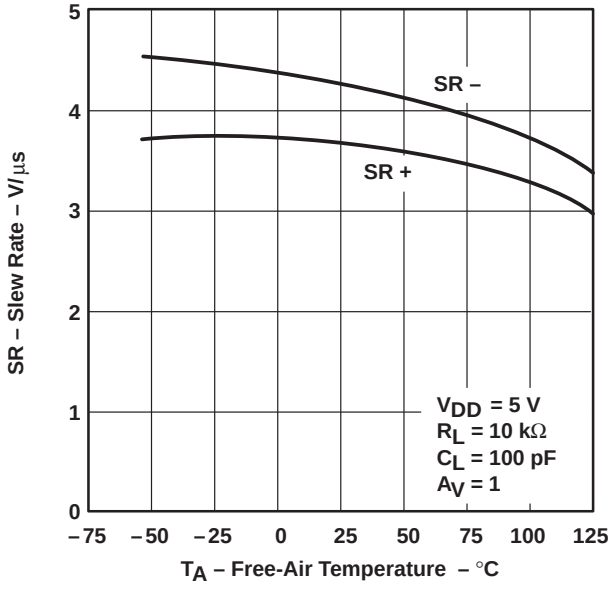


Figure 41

INVERTING LARGE-SIGNAL PULSE RESPONSE

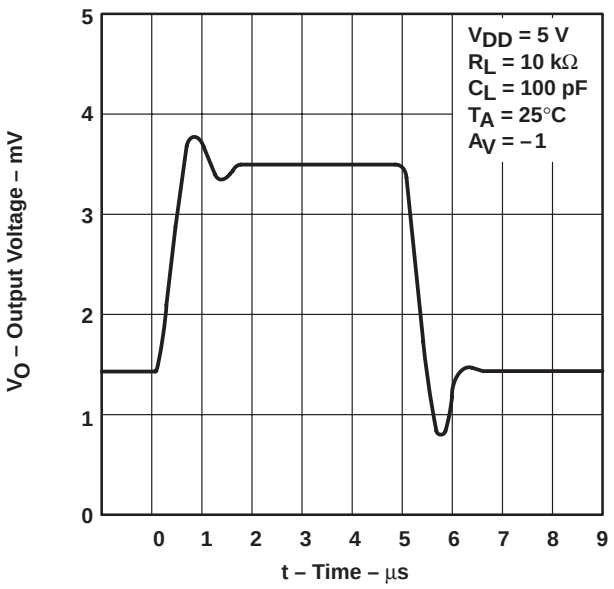


Figure 42

† Data at high and low temperatures are applicable only within the rated operating free-air temperature ranges of the various devices.

TYPICAL CHARACTERISTICS

INVERTING LARGE-SIGNAL PULSE RESPONSE

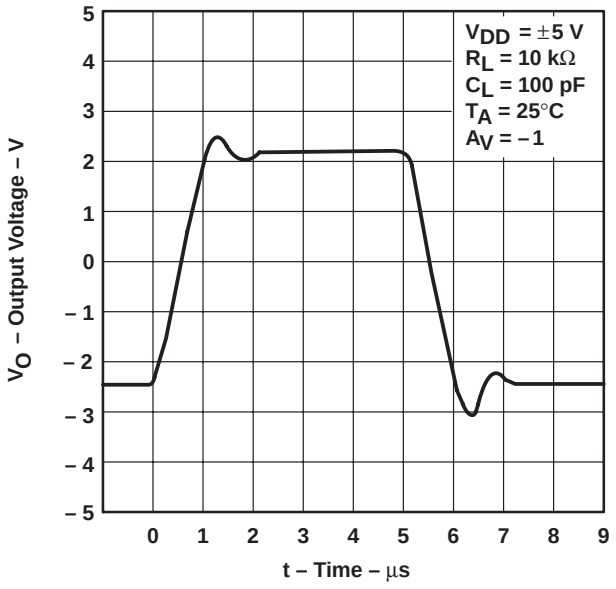


Figure 43

VOLTAGE-FOLLOWER LARGE-SIGNAL PULSE RESPONSE

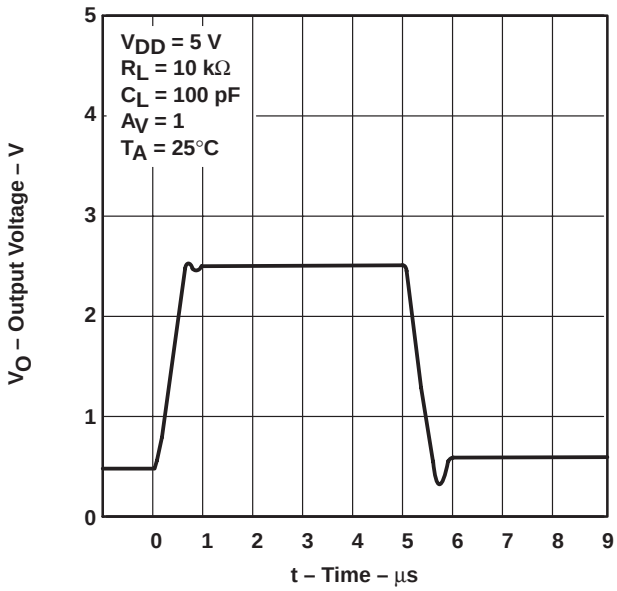


Figure 44

VOLTAGE-FOLLOWER LARGE-SIGNAL PULSE RESPONSE

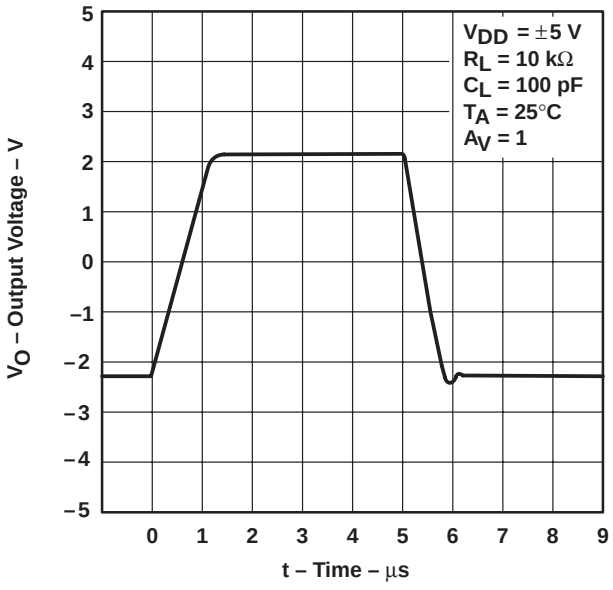


Figure 45

INVERTING SMALL-SIGNAL PULSE RESPONSE

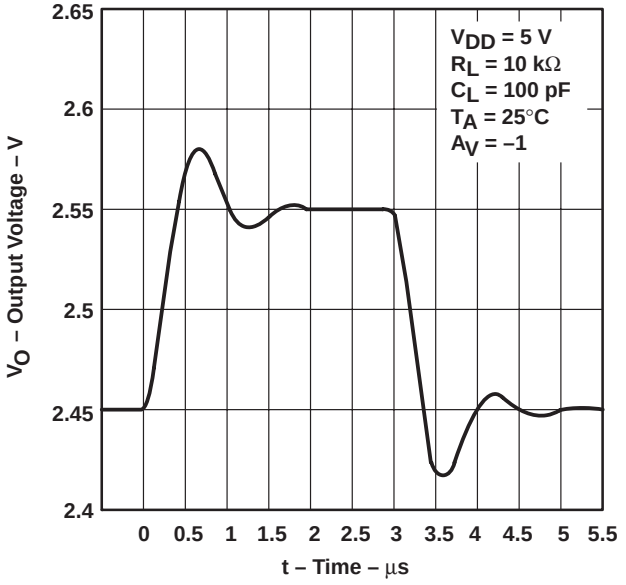


Figure 46

TYPICAL CHARACTERISTICS

INVERTING SMALL-SIGNAL PULSE RESPONSE

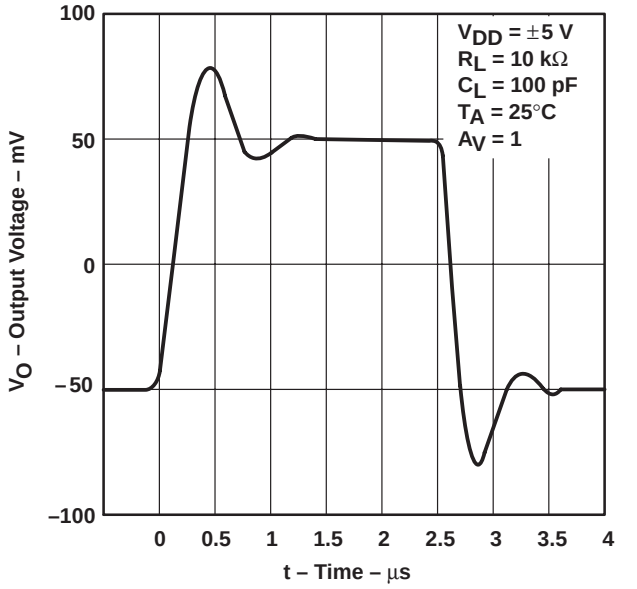


Figure 47

VOLTAGE-FOLLOWER SMALL-SIGNAL PULSE RESPONSE

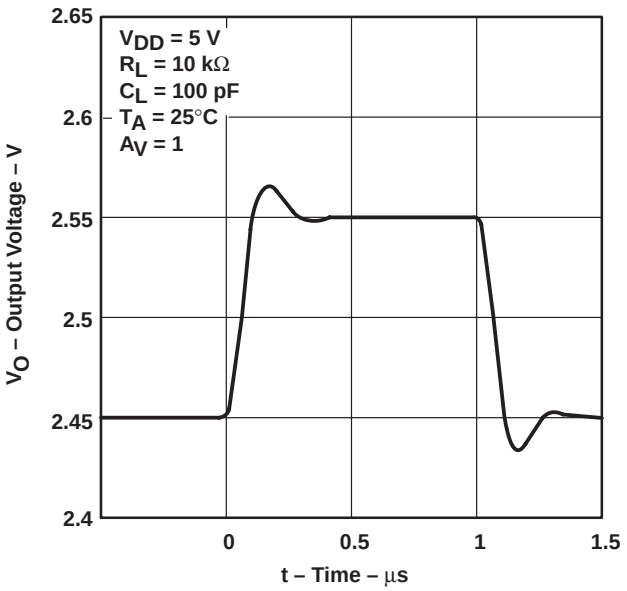


Figure 48

VOLTAGE-FOLLOWER SMALL-SIGNAL PULSE RESPONSE

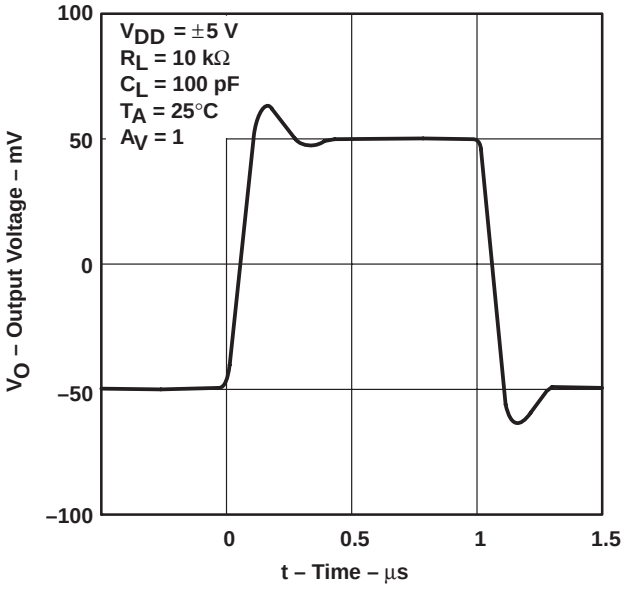


Figure 49

EQUIVALENT INPUT NOISE VOLTAGE vs FREQUENCY

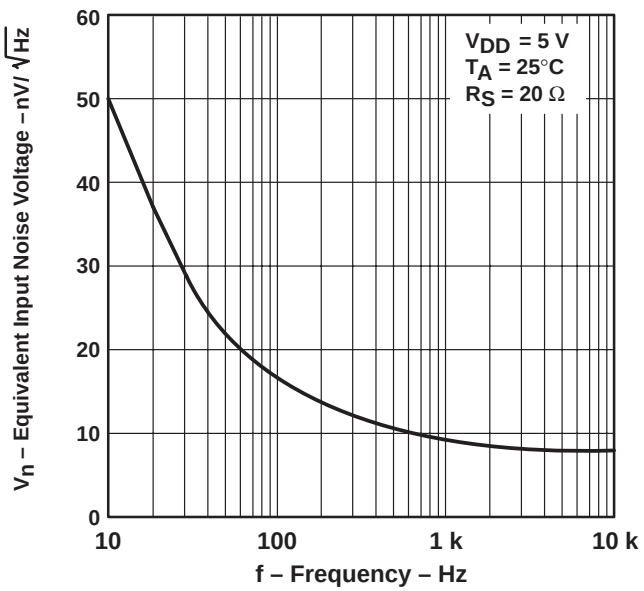


Figure 50

TYPICAL CHARACTERISTICS

EQUIVALENT INPUT NOISE VOLTAGE vs FREQUENCY

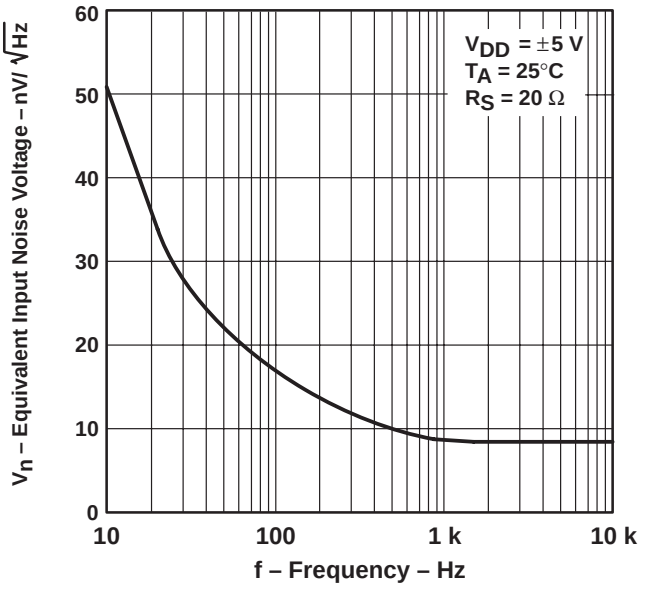


Figure 51

NOISE VOLTAGE OVER A 10 SECOND PERIOD

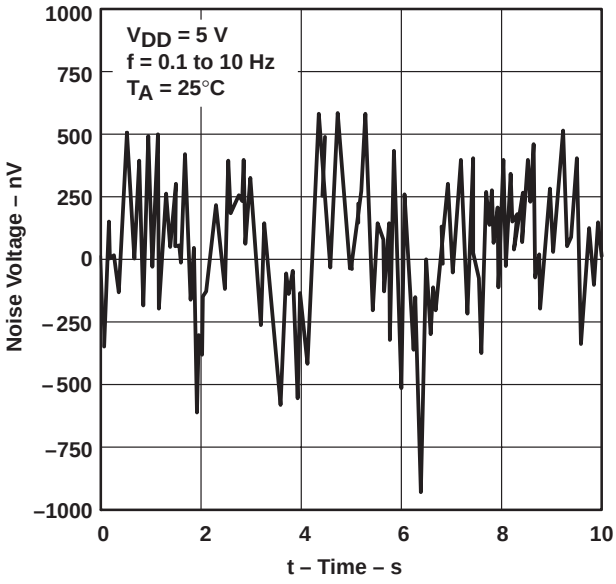


Figure 52

INTEGRATED NOISE VOLTAGE vs FREQUENCY

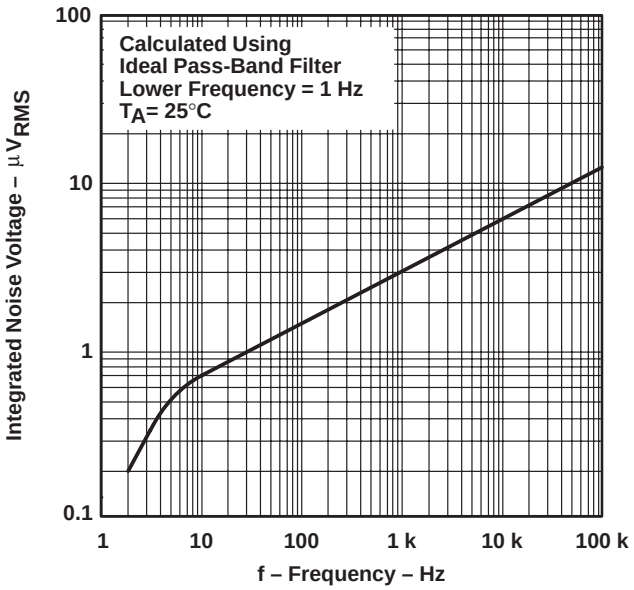


Figure 53

TOTAL HARMONIC DISTORTION PLUS NOISE vs FREQUENCY

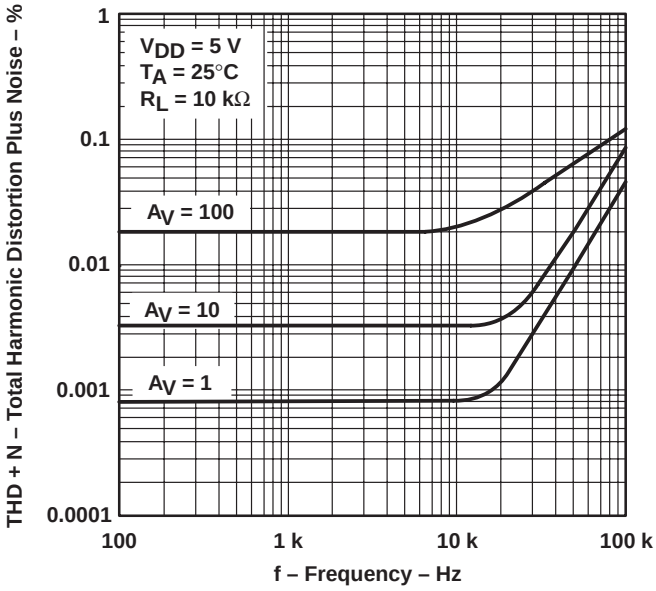


Figure 54

TYPICAL CHARACTERISTICS

GAIN-BANDWIDTH PRODUCT vs SUPPLY VOLTAGE

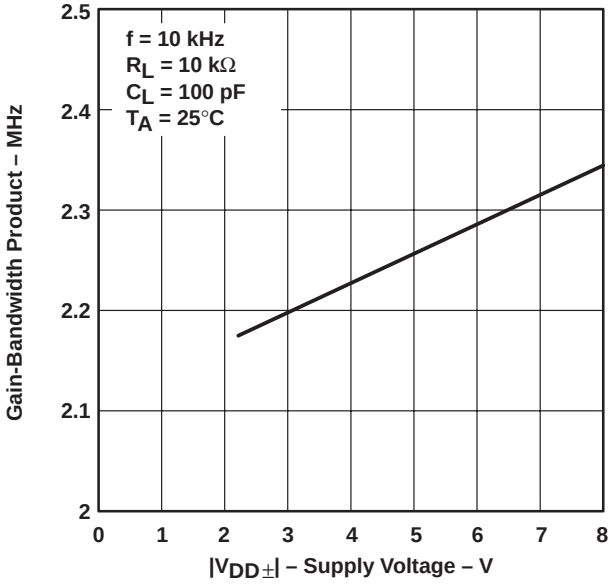


Figure 55

GAIN-BANDWIDTH PRODUCT† vs FREE-AIR TEMPERATURE

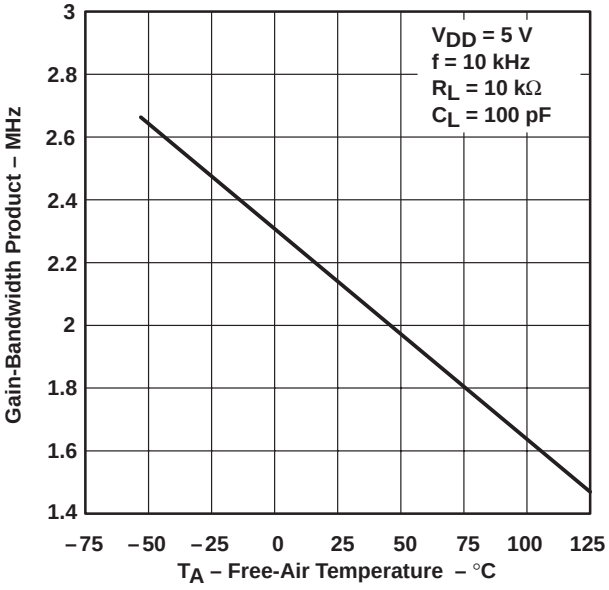


Figure 56

PHASE MARGIN vs LOAD CAPACITANCE

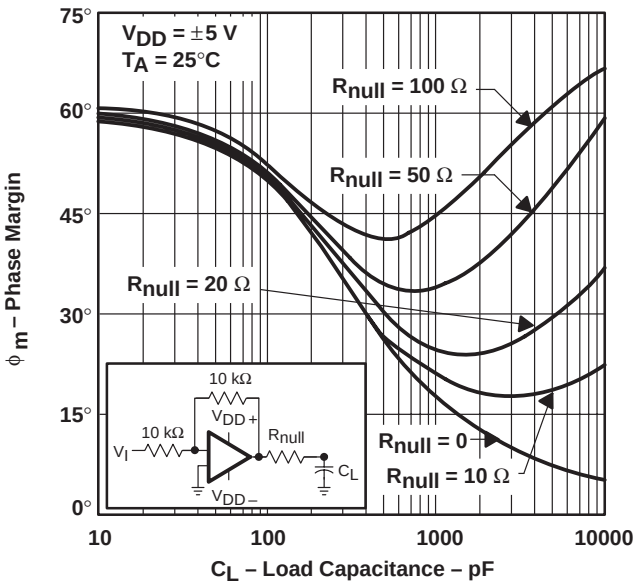


Figure 57

GAIN MARGIN vs LOAD CAPACITANCE

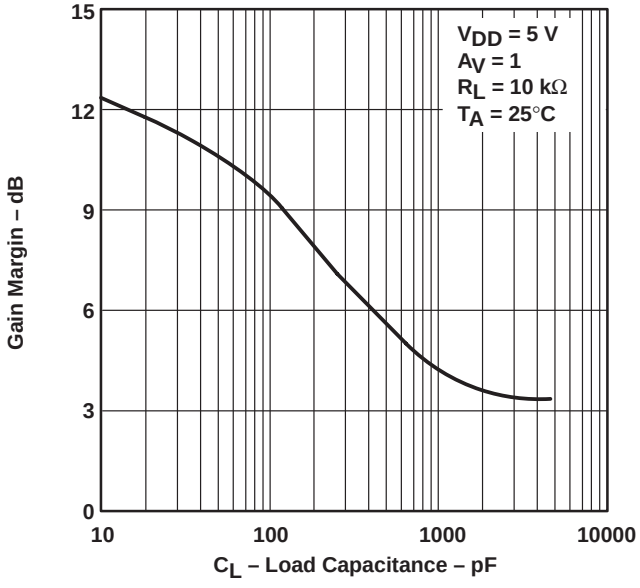


Figure 58

† Data at high and low temperatures are applicable only within the rated operating free-air temperature ranges of the various devices.

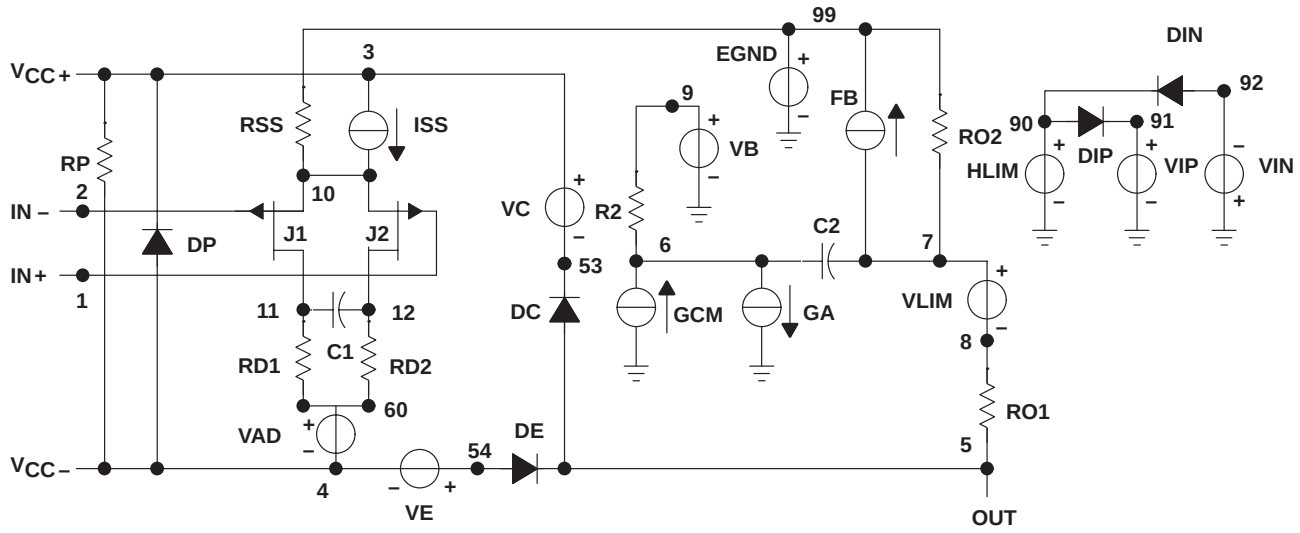
APPLICATION INFORMATION

macromodel information

Macromodel information provided was derived using Microsim *Parts*™, the model generation software used with Microsim *PSpice*™. The Boyle macromodel (see Note 5) and subcircuit in Figure 59 were generated using the TLC227x typical electrical and operating characteristics at T_A = 25°C. Using this information, output simulations of the following key parameters can be generated to a tolerance of 20% (in most cases):

- Maximum positive output voltage swing
- Maximum negative output voltage swing
- Slew rate
- Quiescent power dissipation
- Input bias current
- Open-loop voltage amplification
- Unity gain frequency
- Common-mode rejection ratio
- Phase margin
- DC output resistance
- AC output resistance
- Short-circuit output current limit

NOTE 5: G. R. Boyle, B. M. Cohn, D. O. Pederson, and J. E. Solomon, “Macromodeling of Intergrated Circuit Operational Amplifiers”, *IEEE Journal of Solid-State Circuits,* SC-9, 353 (1974).




```
.SUBCKT TLC227x 1 2 3 4 5
C1      11      12      1214E–12
C2      6       7       760.00E–12
DC      5       53      53DX
DE      54      5       5DX
DLP     90      91      91DX
DLN     92      90      90DX
DP      4       3       3DX
EGND    99      0       0POLY (2) (3,0) (4,) 0 .5 .5
FB      99      0       0POLY (5) VB VC VE VLP VLN 0
+ 984.9E3 –1E6 1E6 1E6 –1E6
GA      6       0       011 12 377.0E–6
GCM 0 6 10 99 134E–9
ISS     3       10      DC 216.OE–6
HLIM    90      0       VLIM 1K
J1      11      2       10 JX
J2      12      2       10 JX
R2      6       9       100.OE3
RD1     60      11      12.653E3
RD2     60      12      122.653E3
R01     8       5       50
R02     7       99      950
RP      3       2       4.310E3
RSS     10      99      925.9E3
VAD     60      4       –.5
VB      9       0       DC 0
VC 3 53 DC .78
VE      54      4       DC .78
VLIM    7       8       DC 0
VLP     91      0       DC 1.9
VLN     0       92      DC 9.4
.MODEL DX D (IS=800.0E–18)
.MODEL JX PJF (IS=1.500E–12BETA=1.316E-3
+ VTO=–.270)
.ENDS
```

Figure 59. Boyle Macromodel and Subcircuit

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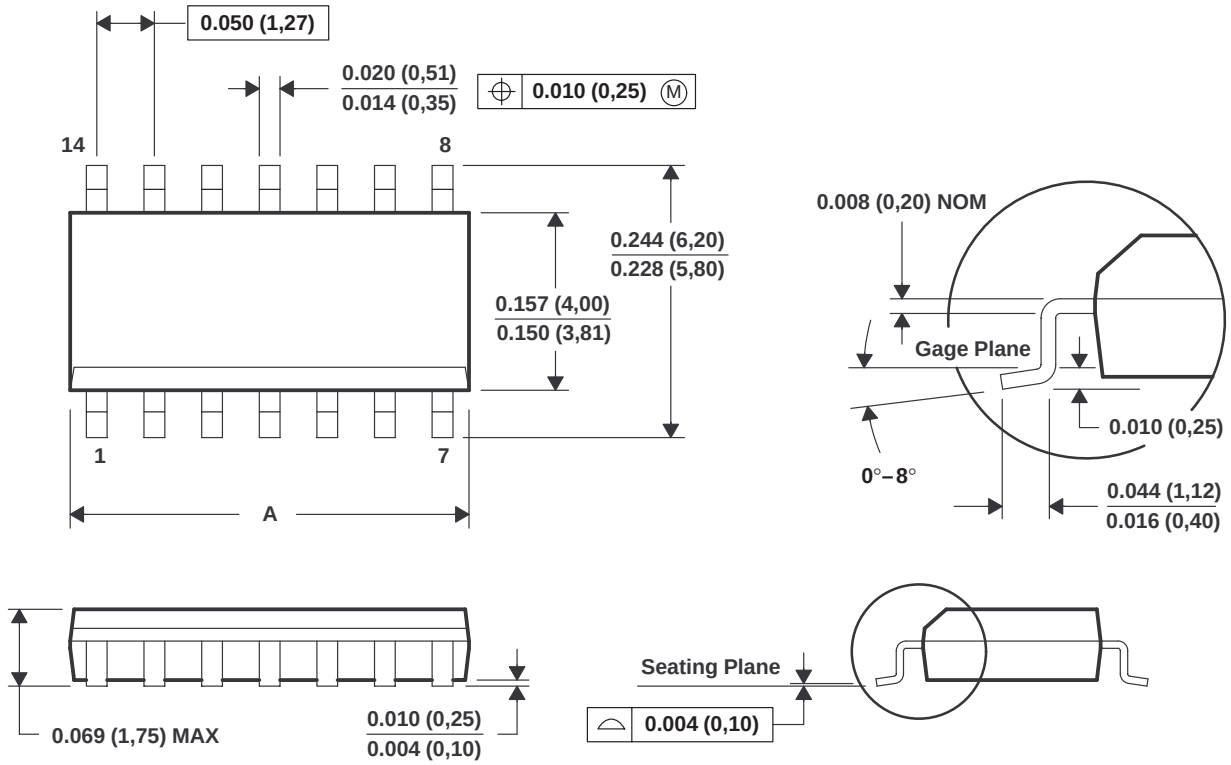
MECHANICAL DATA

D (R-PDSO-G)** **PLASTIC SMALL-OUTLINE PACKAGE**

14 PIN SHOWN



DIM \ PINS **	8	14	16
A MAX	0.197 (5,00)	0.344 (8,75)	0.394 (10,00)
A MIN	0.189 (4,80)	0.337 (8,55)	0.386 (9,80)

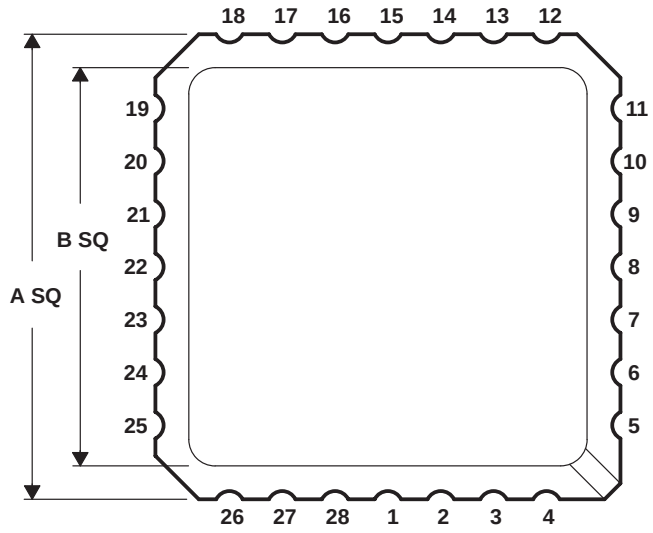
4040047/D 10/96

NOTES: A. All linear dimensions are in inches (millimeters).
B. This drawing is subject to change without notice.
C. Body dimensions do not include mold flash or protrusion, not to exceed 0.006 (0,15).
D. Falls within JEDEC MS-012

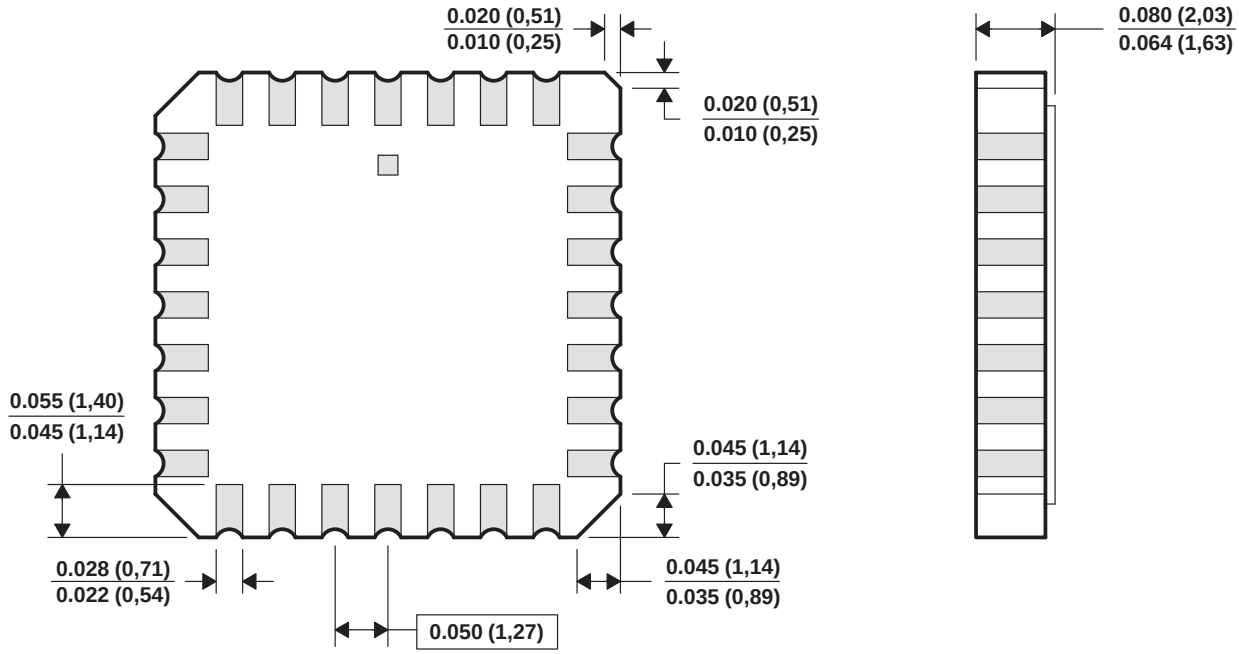
MECHANICAL DATA

FK (S-CQCC-N)** **LEADLESS CERAMIC CHIP CARRIER**

28 TERMINAL SHOWN



NO. OF TERMINALS **	A		B	
	MIN	MAX	MIN	MAX
20	0.342 (8,69)	0.358 (9,09)	0.307 (7,80)	0.358 (9,09)
28	0.442 (11,23)	0.458 (11,63)	0.406 (10,31)	0.458 (11,63)
44	0.640 (16,26)	0.660 (16,76)	0.495 (12,58)	0.560 (14,22)
52	0.739 (18,78)	0.761 (19,32)	0.495 (12,58)	0.560 (14,22)
68	0.938 (23,83)	0.962 (24,43)	0.850 (21,6)	0.858 (21,8)
84	1.141 (28,99)	1.165 (29,59)	1.047 (26,6)	1.063 (27,0)



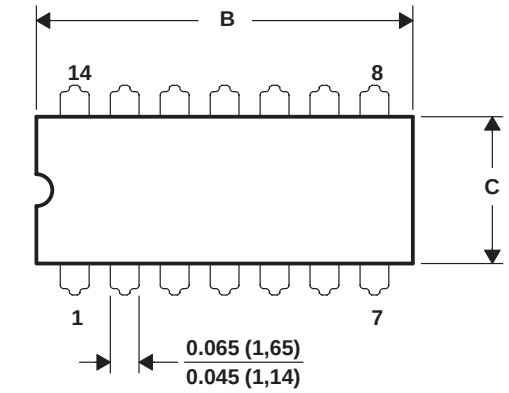
4040140/D 10/96

NOTES: A. All linear dimensions are in inches (millimeters).
B. This drawing is subject to change without notice.
C. This package can be hermetically sealed with a metal lid.
D. The terminals are gold plated.
E. Falls within JEDEC MS-004

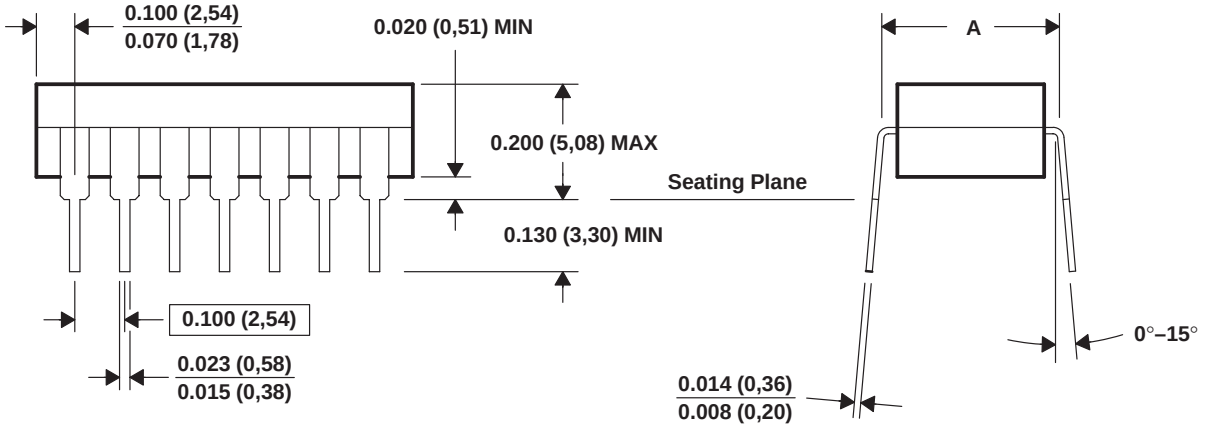
MECHANICAL DATA

J (R-GDIP-T)** **CERAMIC DUAL-IN-LINE PACKAGE**

14 PIN SHOWN



DIM \ PINS **	14	16	18	20
A MAX	0.310 (7,87)	0.310 (7,87)	0.310 (7,87)	0.310 (7,87)
A MIN	0.290 (7,37)	0.290 (7,37)	0.290 (7,37)	0.290 (7,37)
B MAX	0.785 (19,94)	0.785 (19,94)	0.910 (23,10)	0.975 (24,77)
B MIN	0.755 (19,18)	0.755 (19,18)	—	0.930 (23,62)
C MAX	0.300 (7,62)	0.300 (7,62)	0.300 (7,62)	0.300 (7,62)
C MIN	0.245 (6,22)	0.245 (6,22)	0.245 (6,22)	0.245 (6,22)



4040083/D 08/98

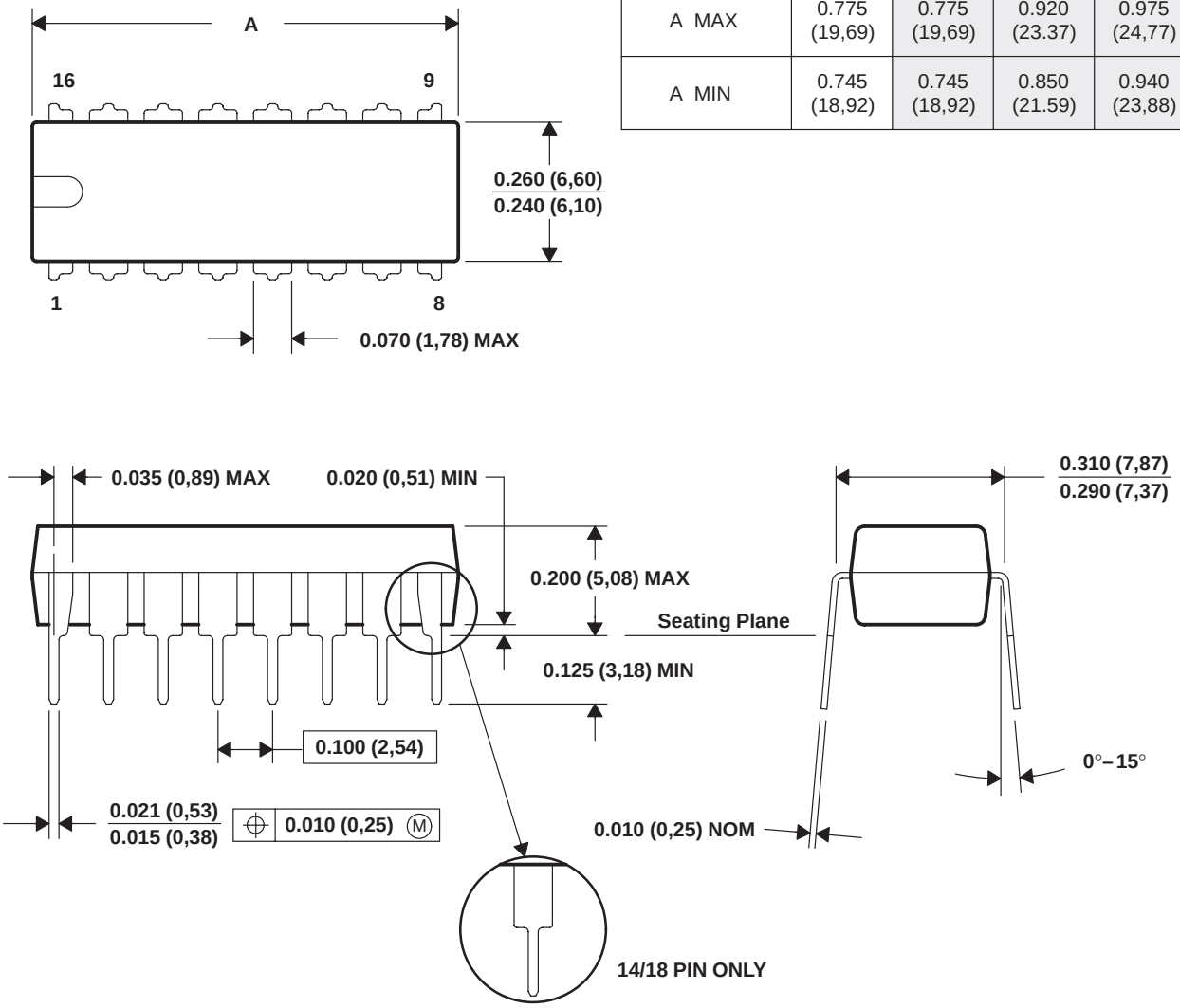
NOTES: A. All linear dimensions are in inches (millimeters).
B. This drawing is subject to change without notice.
C. This package can be hermetically sealed with a ceramic lid using glass frit.
D. Index point is provided on cap for terminal identification only on press ceramic glass frit seal only.
E. Falls within MIL STD 1835 GDIP1-T14, GDIP1-T16, GDIP1-T18, GDIP1-T20, and GDIP1-T22.

MECHANICAL DATA

N (R-PDIP-T)** **PLASTIC DUAL-IN-LINE PACKAGE**

16 PIN SHOWN

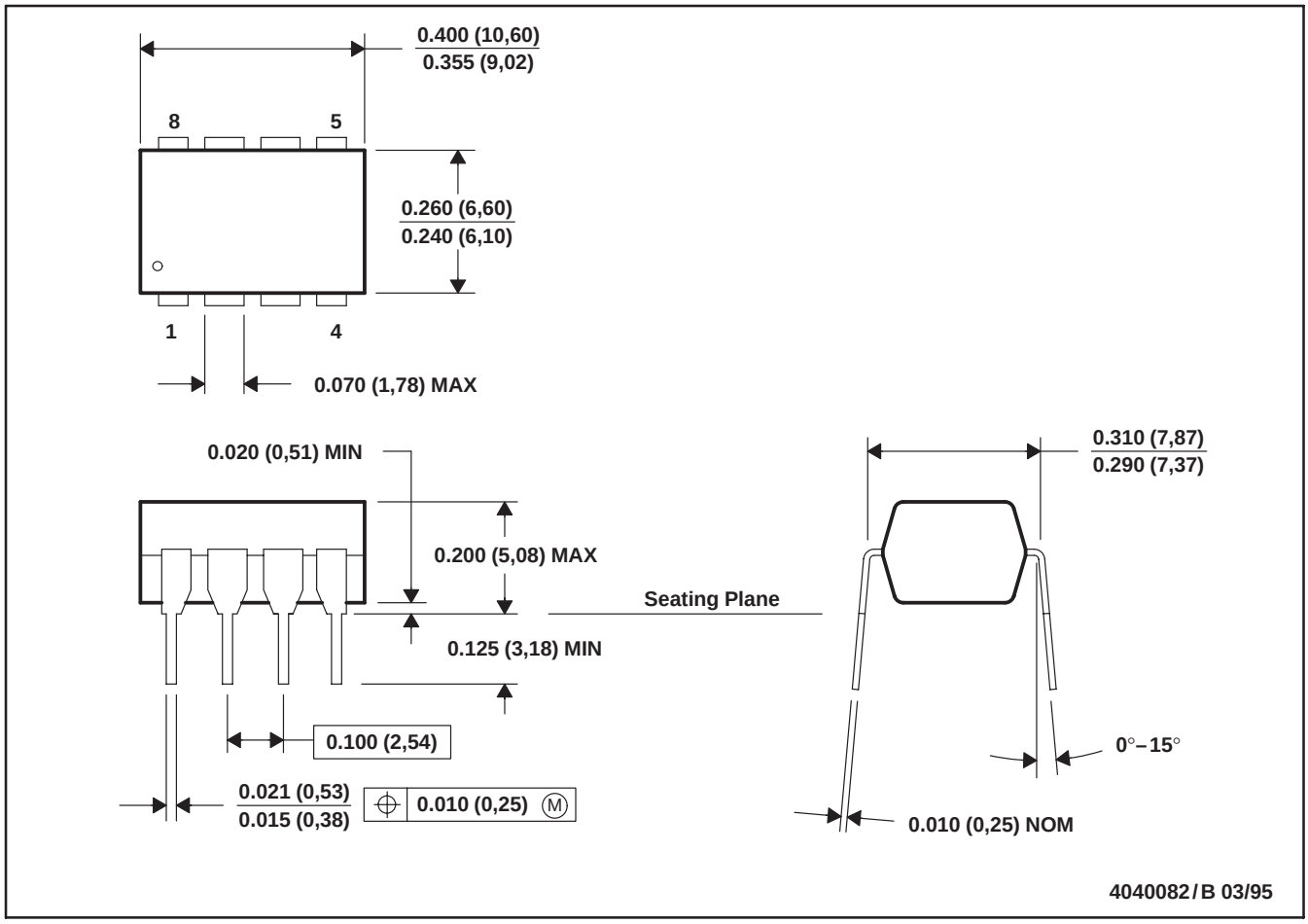
DIM \ PINS **	14	16	18	20
A MAX	0.775 (19,69)	0.775 (19,69)	0.920 (23.37)	0.975 (24,77)
A MIN	0.745 (18,92)	0.745 (18,92)	0.850 (21.59)	0.940 (23,88)



NOTES: A. All linear dimensions are in inches (millimeters).
B. This drawing is subject to change without notice.
C. Falls within JEDEC MS-001 (20 pin package is shorter then MS-001.)

MECHANICAL DATA

P (R-PDIP-T8) **PLASTIC DUAL-IN-LINE PACKAGE**

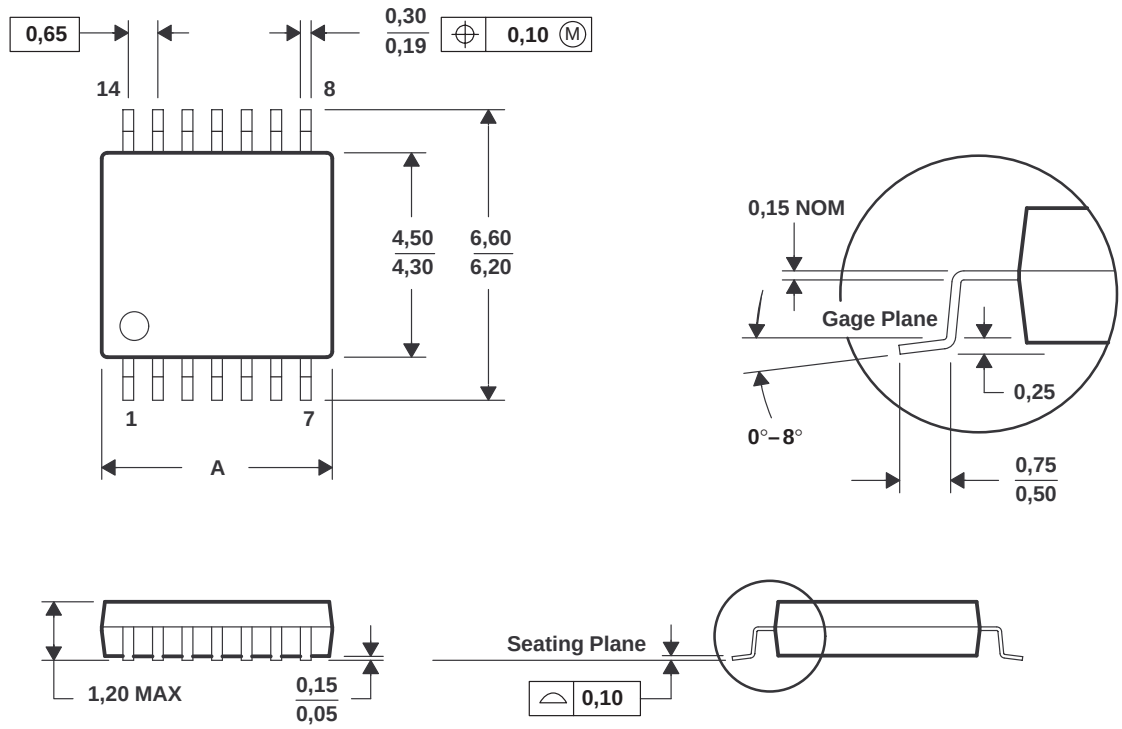


NOTES: A. All linear dimensions are in inches (millimeters).
B. This drawing is subject to change without notice.
C. Falls within JEDEC MS-001

MECHANICAL DATA

PW (R-PDSO-G)** **PLASTIC SMALL-OUTLINE PACKAGE**

14 PIN SHOWN



DIM \ PINS **	8	14	16	20	24	28
A MAX	3,10	5,10	5,10	6,60	7,90	9,80
A MIN	2,90	4,90	4,90	6,40	7,70	9,60

4040064/E 08/96

NOTES: A. All linear dimensions are in millimeters.
B. This drawing is subject to change without notice.
C. Body dimensions do not include mold flash or protrusion not to exceed 0,15.
D. Falls within JEDEC MO-153

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